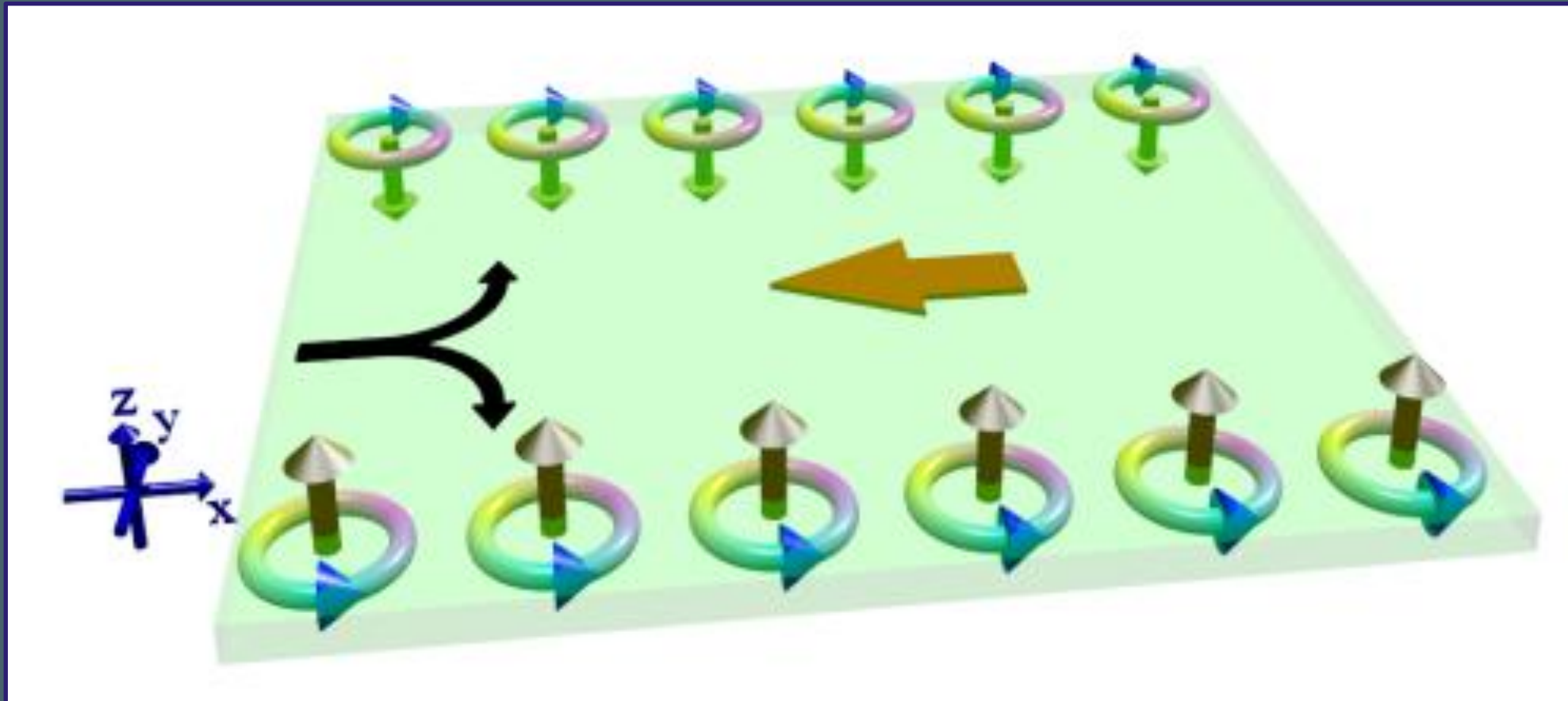


Orbitronics: from transport to topology

Speaker: **Tarik P. Cysne** (UFF-RJ)

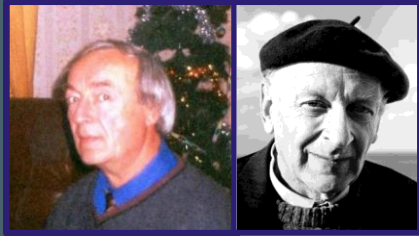


Part I: Introduction



Brief History

Theory: Dyakonov-Perel



(1971)

Intense activity in SHE:

- Intrinsic x extrinsic
- Quantum SHE
- Topological Insulators

...

Poor interest in OHE

Direct experimental observation of OHE!

(1879)



Hall effect

(1965)



Mott Scattering

(1999/2000)



Theory/Experiment:
Spin Hall Effect
(Mott mechanism)

(2005/06)



Theory:
Orbital Hall effect
(analog to SHE)

(2016) (2021/22)

Renewed interest in
the OHE pushed by
theoretical works.

Extrinsic mechanism
(impurity dependent)

Intrinsic mechanism
(Band structure)

Motivation



Motivation

Changing the paradigm of information technology

Spintronics: Use the spin of e^- (\hat{S}) to store and process information

Fundamentals of spintronics:

- 1 -spin-injection
- 2 -spin-manipulation
- 3 -spin-detection

Preferable by electrical means (\vec{E})

Problem: \vec{E} does not couple directly with \hat{S} ... ☹ ☹ ☹

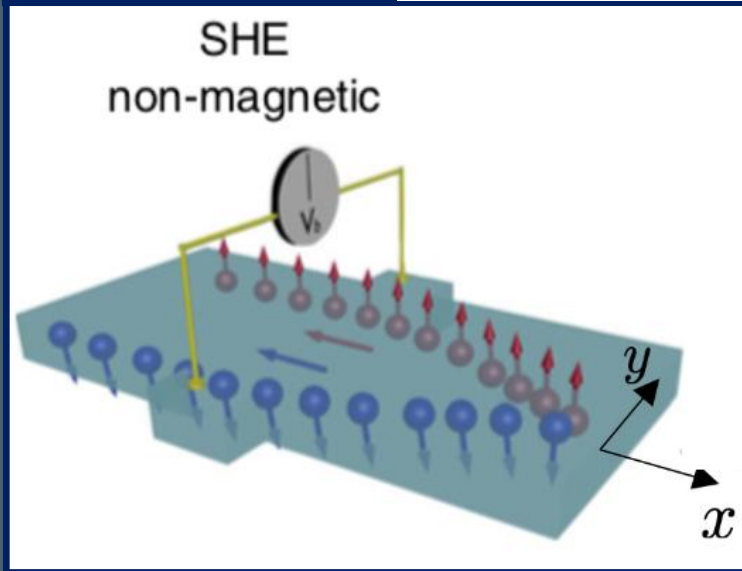
The use of materials with strong spin-orbit coupling (SOC).



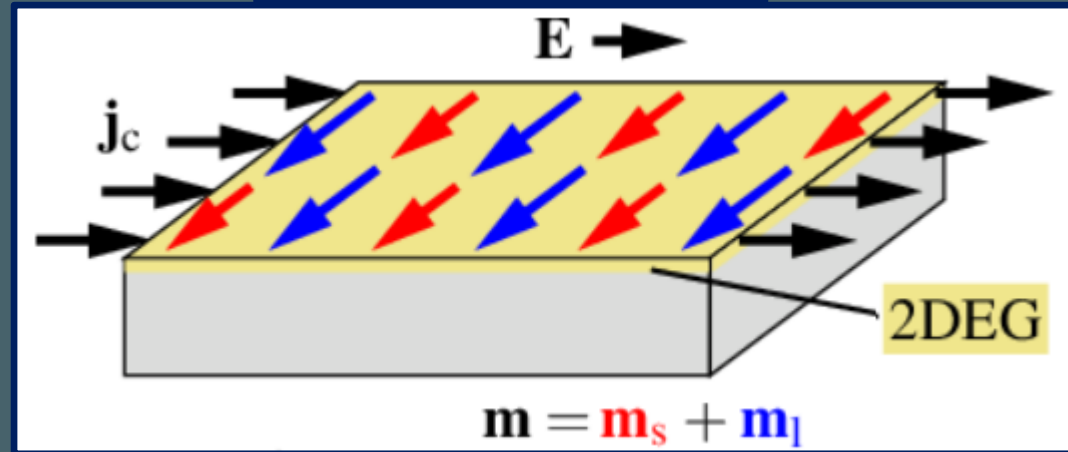
Some Important effects in spintronics

Spin Hall effect

[J. Sinova, et. al.
RPM. 87, 1213 (2015)]

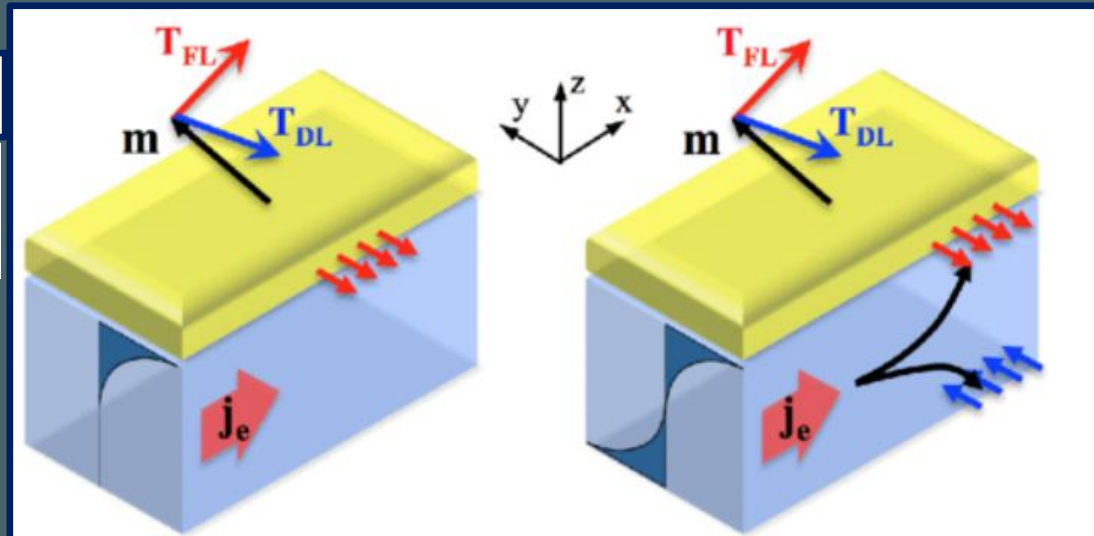


Spin Edelstein effect

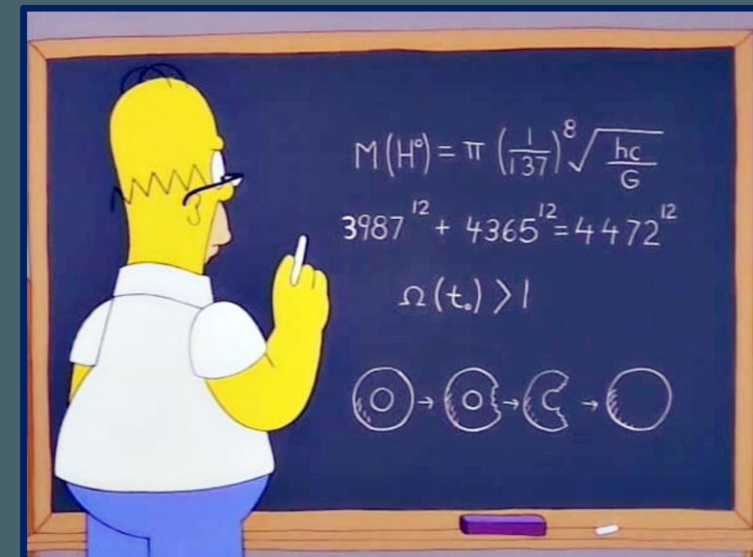


Spin-orbit torque

[A. Manchon, et. al.
RPM. 91, 035004 (2019)]

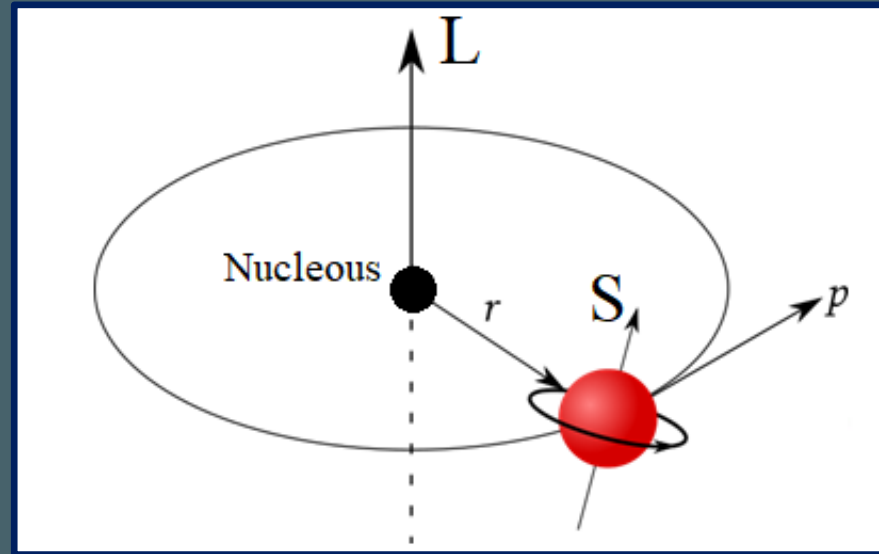


Can we overcome the need
for strong spin-orbit coupling?

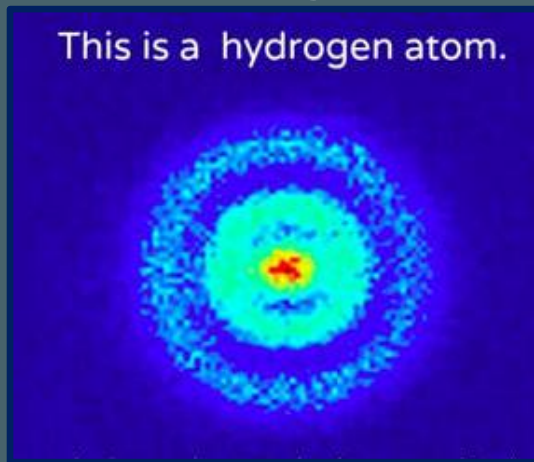


From Beginning

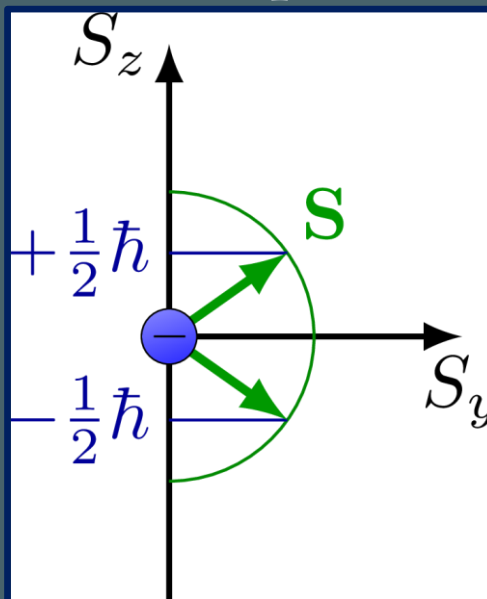
An atom:



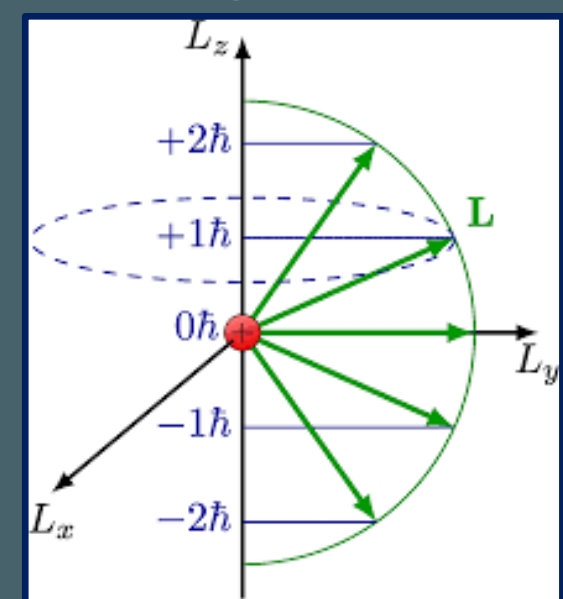
Charge:



e^- -Spin:

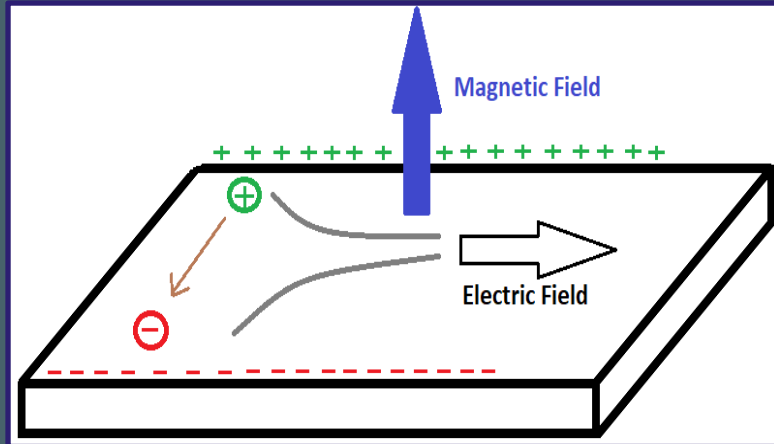


e^- -Orbital angular momentum:



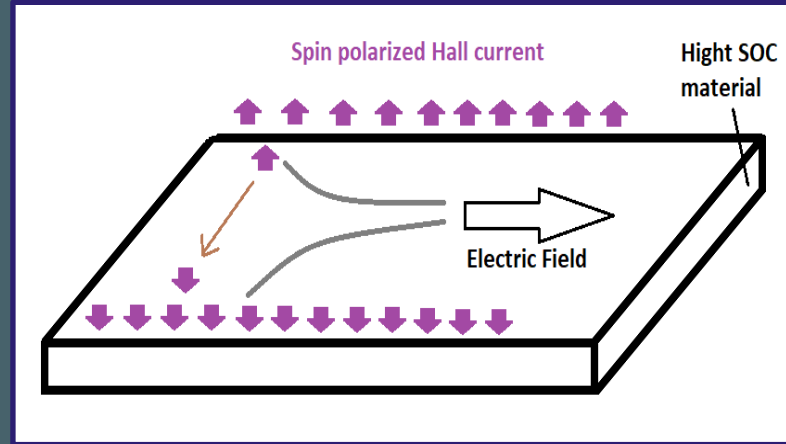
Hall Effects

“Charge” Hall Effect



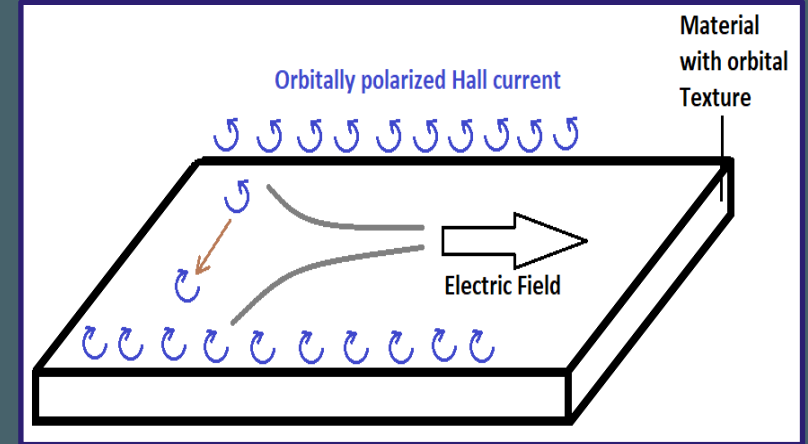
Time Reversal Symmetry
Breaking
(E.g. External Magnetic
Field)

Spin Hall Effect (SHE)



High SOC systems
(E.g. material with a high
atomic number Z ☹️)

Orbital Hall Effect (OHE)

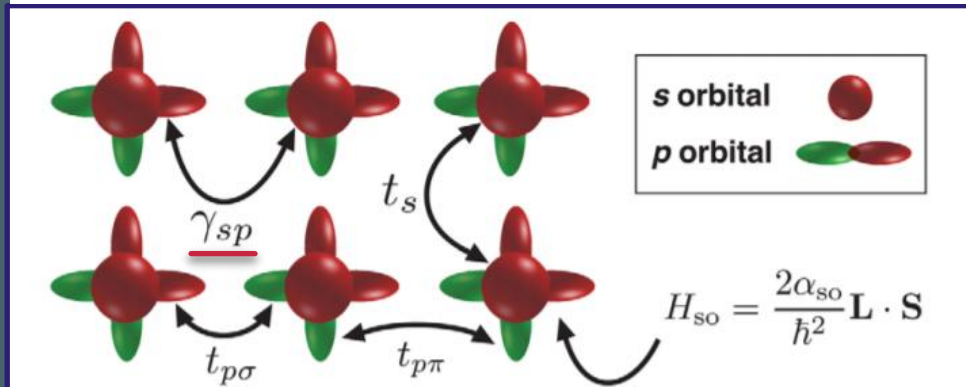


Solids with multi-orbital
texture and strong inter-
orbital hybridization

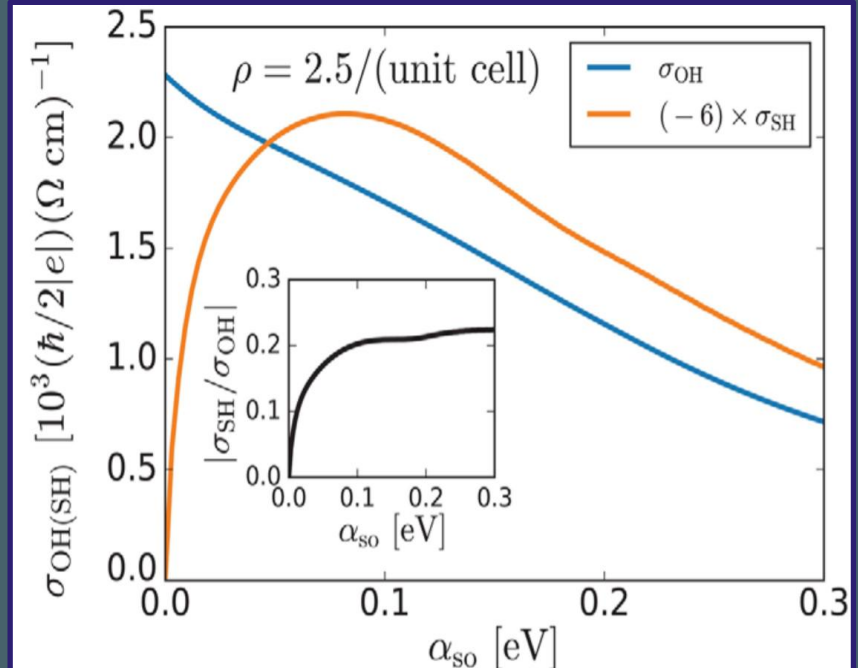
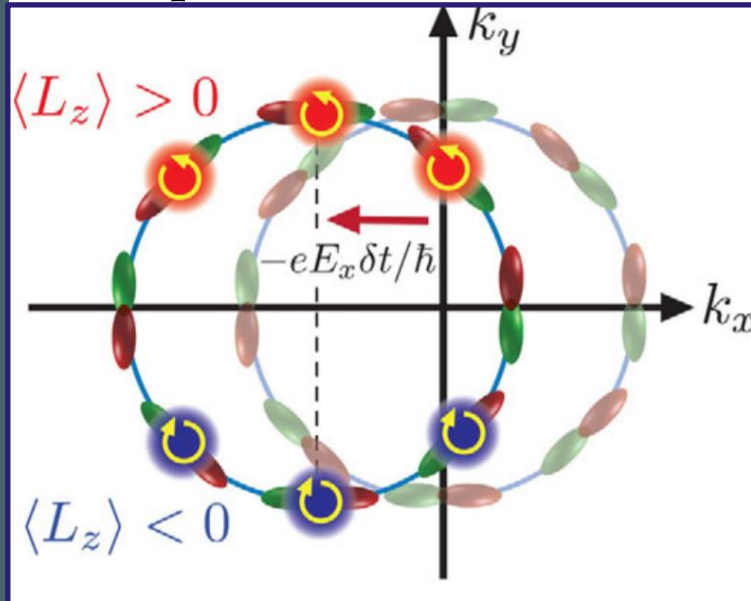
(Occurs even in the
absence of SOC 😊)

Intrinsic mechanism of OHE (3D Metals)

Multi-orbital solid with sp Hybridization



Intrinsic OHE is a consequence of **orbital texture**:



- (i)- OHE precedes the SHE
- (ii)- The OHE is converted in SHE by SOC: $\vec{L} \cdot \vec{S}$
- (iii)- The OHE occurs even in absence of SOC! 😊 😊 😊

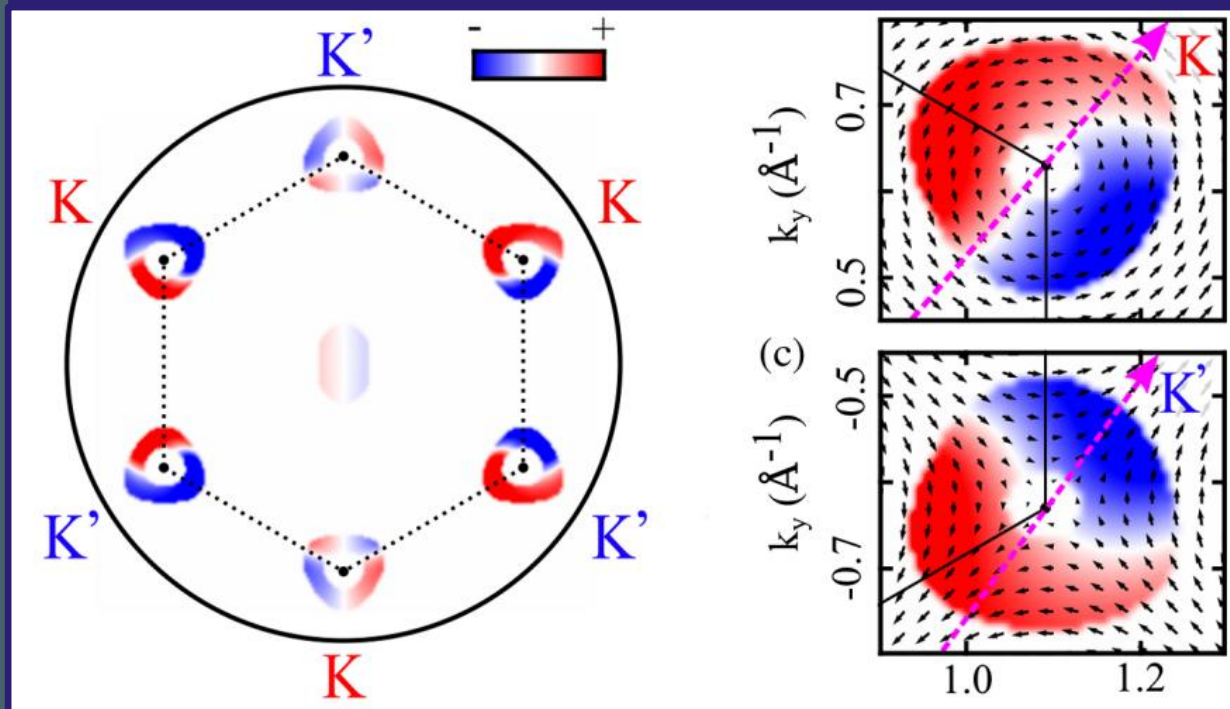
[D. Go, et. al. PRL. 121, 086602 (2018)]

Orbital Textures

OAM texture: $\langle L_{x,y,z} \rangle = \langle u_{nk} | \hat{L}_{x,y,z} | u_{nk} \rangle$

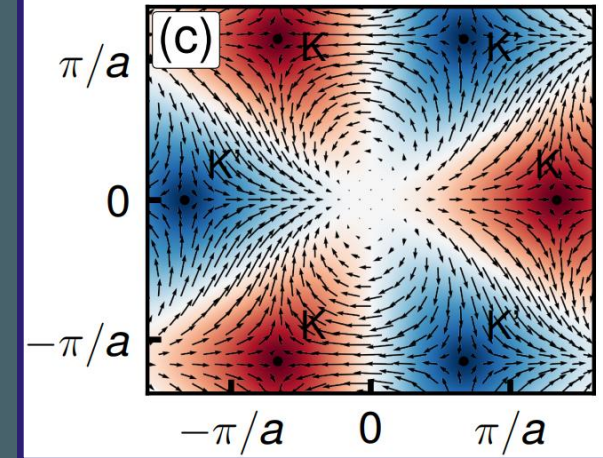
Experiment

Can be measured by TRDPAD (time-reversal dichroism in photoelectron angular distributions):



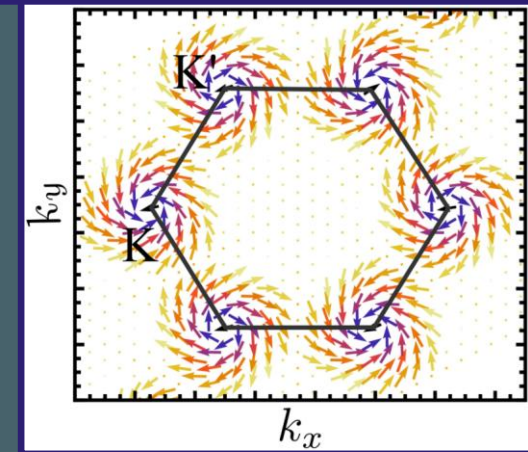
[S. Beaulieu, et.al. PRL 125, 216404 (2020)]

Valence band of 1L-MoS2 (Theory)



[L. Canonico, et.al. PRB 101, 161409(R)(2020)]

Borophene monolayer (Theory)



[F. Crasto de Lima, et.al.,
Nano Lett. 19 (9) 6564(2019)]

Important groups are studying orbitronics

nature communications

Article

<https://doi.org/10.1038/s41467-024-46405-6>

Orbitronics: light-induced orbital currents in Ni studied by terahertz emission experiments

Received: 15 July 2023

Accepted: 26 February 2024

Published online: 06 March 2024

Yong Xu^{1,2,3,5}, Fan Zhang^{3,5}, Albert Fert^{2,4,5} ✉, Henri-Yves Jaffres^{4,5},
Yongshan Liu^{2,3}, Renyou Xu^{2,3}, Yuhao Jiang², Houyi Cheng^{2,3} &
Weisheng Zhao^{1,2,3} ✉

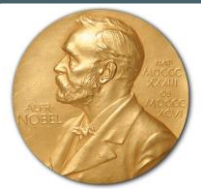
nature

Observation of the orbital Hall effect in a light metal Ti

[Young-Gwan Choi](#), [Daeyeon Jo](#), [Kyung-Hun Ko](#), [Dongwook Go](#), [Kyung-Han Kim](#), [Hee Gyum Park](#),
[Changyoung Kim](#), [Byoung-Chul Min](#), [Gyung-Min Choi](#) ✉ & [Hyun-Woo Lee](#) ✉

Nature 619, 52–56 (2023) | [Cite this article](#)

Albert Fert !

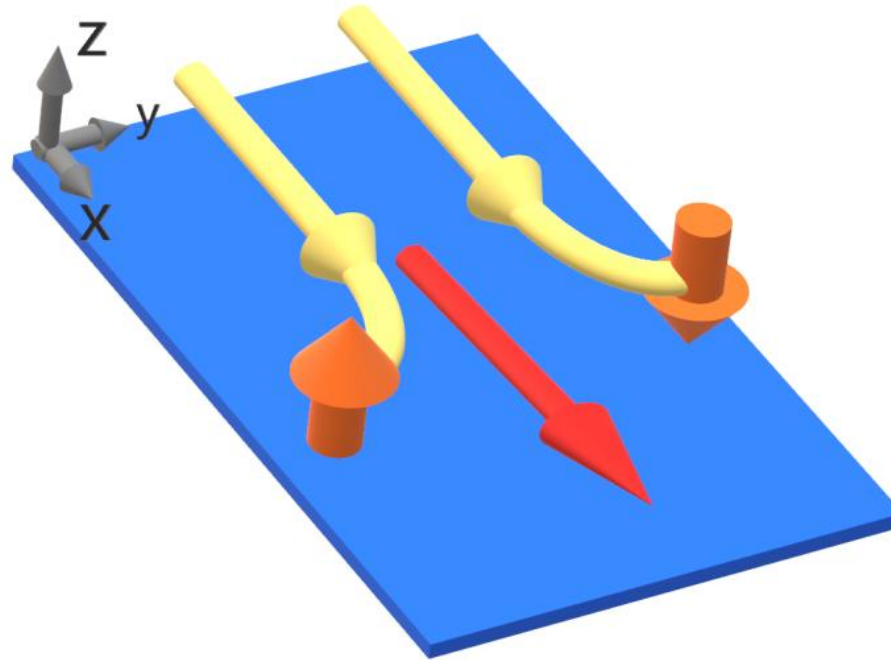


Now... let's talk about some
of our work works :
Orbitronics in 2D materials



Part II:

Orbital Hall effect



Orbital Hall Conductivity

$$\frac{\Omega_{n,\vec{k}}^{X_z}}{2\hbar} = \sum_{m \neq n} \text{Im} \left[\frac{\langle u_{n,\vec{k}} | \hat{v}_x(\vec{k}) | u_{m,\vec{k}} \rangle \langle u_{m,\vec{k}} | \hat{J}_y^{X_z}(\vec{k}) | u_{n,\vec{k}} \rangle}{(E_{n,\vec{k}} - E_{m,\vec{k}})^2} \right]$$

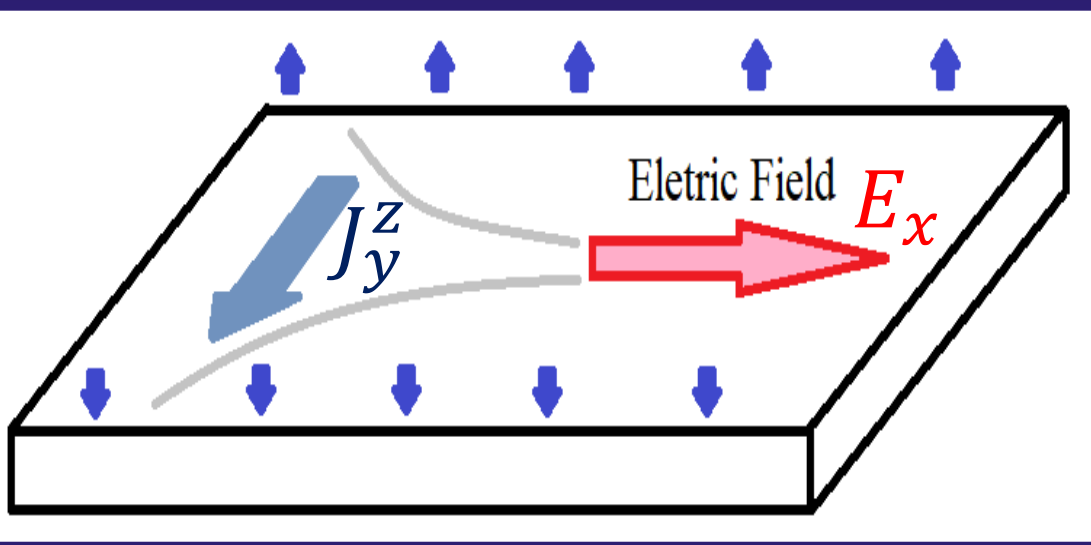
$$\sigma_{\text{OH}}^{X_z} = e \sum_n \int \frac{d^2k}{(2\pi)^2} f_{n,\vec{k}} \Omega_{n,\vec{k}}^{X_z}$$

[T. P. Cysne, et. al., PRB 105, 195421 (2022)]

Orbital current operator:

$$\hat{J}_y^{L_z}(\vec{k}) = \frac{1}{2} [L_z \hat{v}_y(\vec{k}) + \hat{v}_y(\vec{k}) L_z]$$

Intra-atomic approximation
(Localized electronic orbits)



$$\langle J_y^{L_z} \rangle = \sigma_{OH}^{L_z} \mathcal{E}_x$$



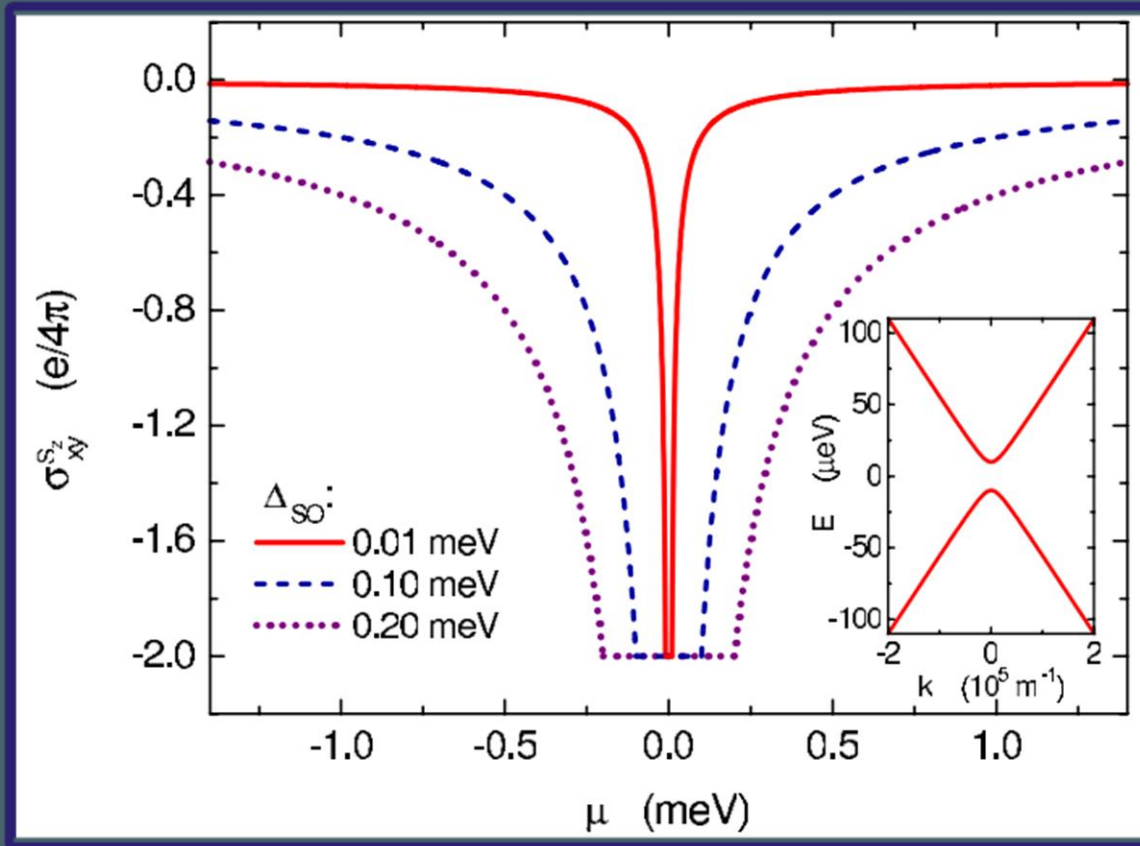
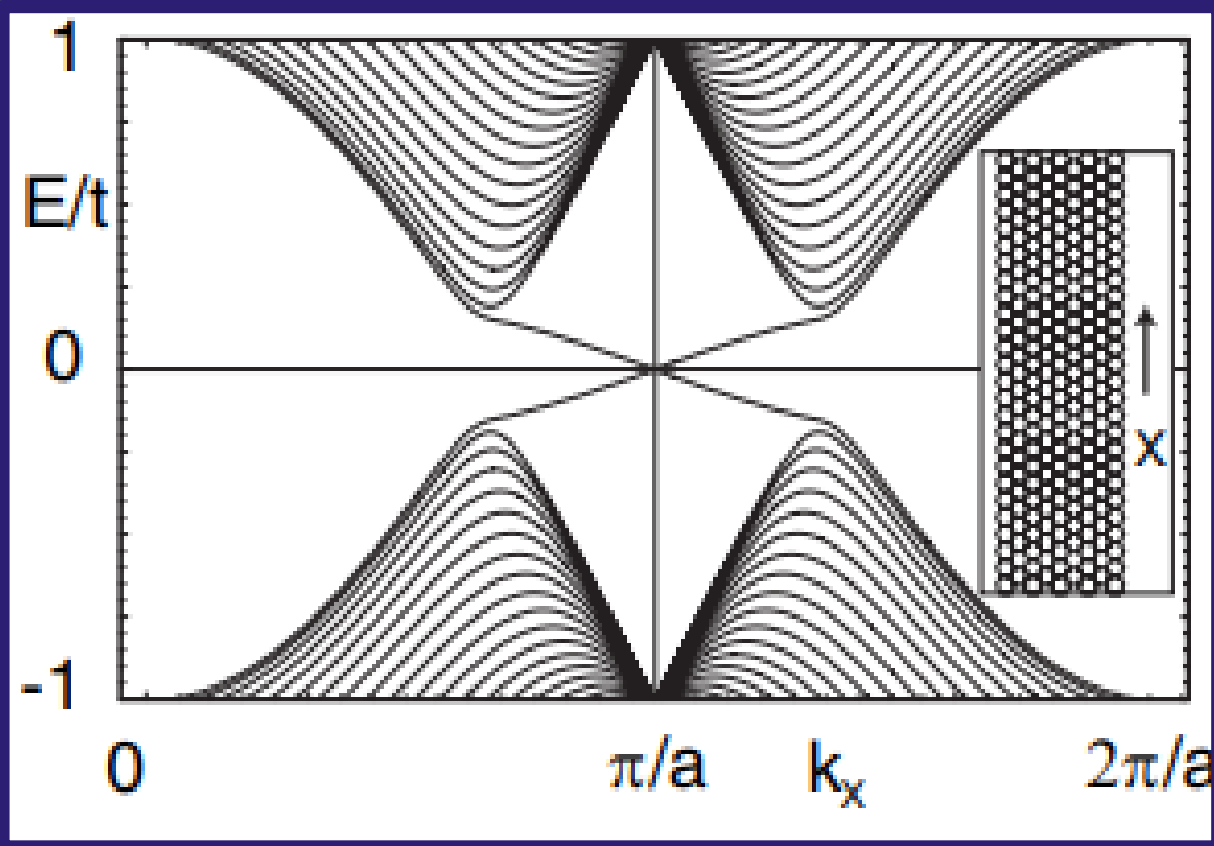
Talking about spin again (Quantum Spin Hall insulators Paradigm)



$$\langle J_y^{S_z} \rangle = \sigma_{SH}^{S_z} \mathcal{E}_x$$

$$\sigma_{SH}^{S_z} = \frac{e}{2\pi} C_S$$

Spin Chern number



Talking about spin again

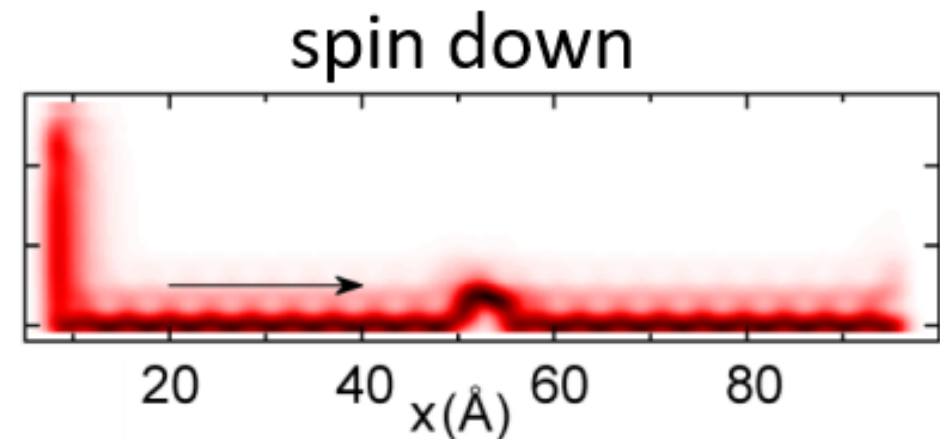
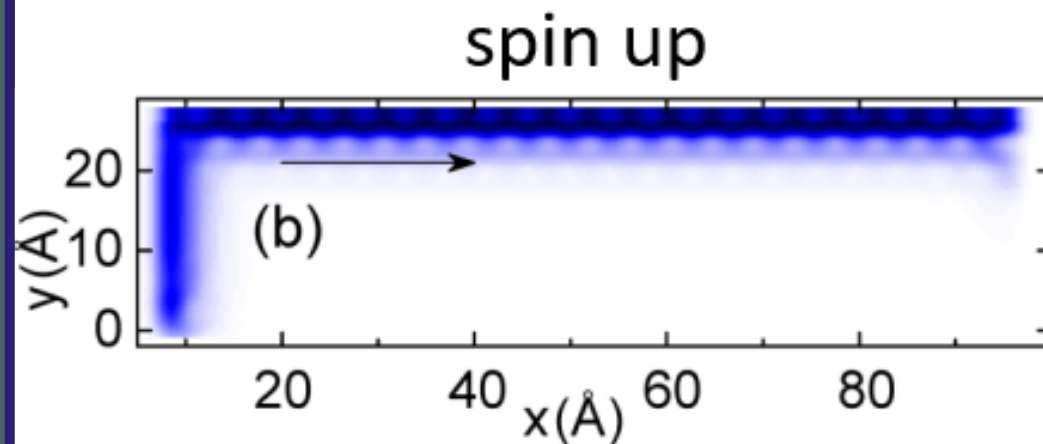
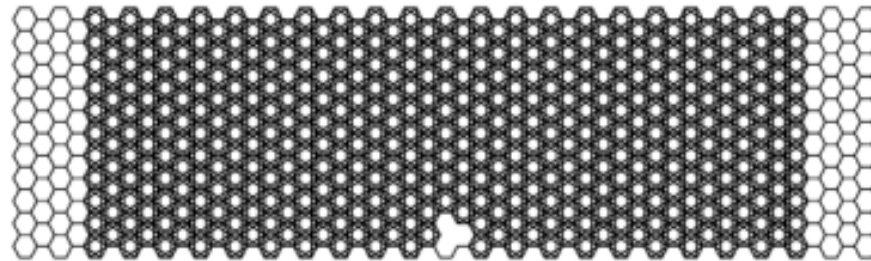
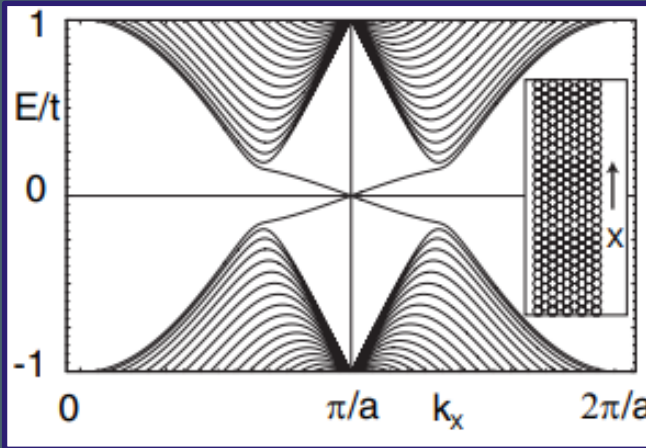
(Quantum Spin Hall insulators Paradigm)



$$\langle J_y^{S_z} \rangle = \sigma_{SH}^{S_z} \mathcal{E}_x$$

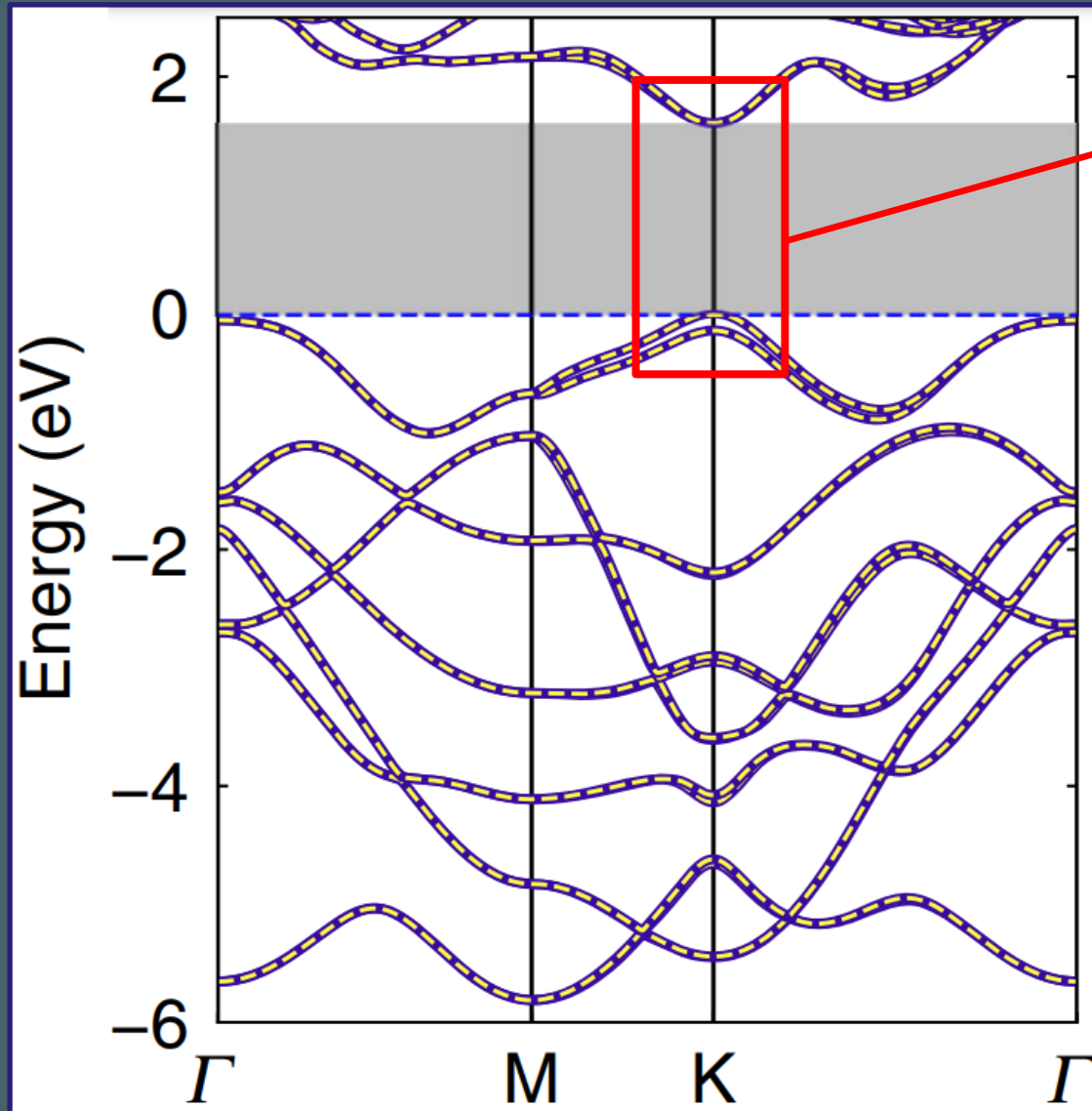
$$\sigma_{SH}^{S_z} = \frac{e}{2\pi} C_S$$

[L.F. Lima and C. Lewenkopf PRB 106, 245408 (2022)]



Multi-Orbital Two-dimensional materials

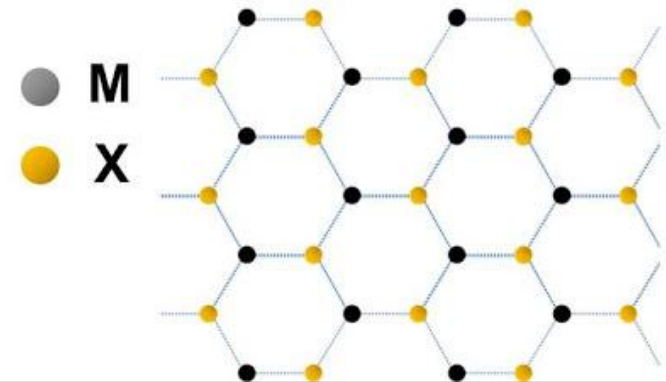
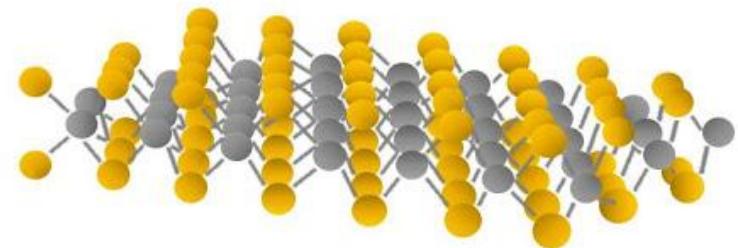
Monolayer of 2H-MoS₂



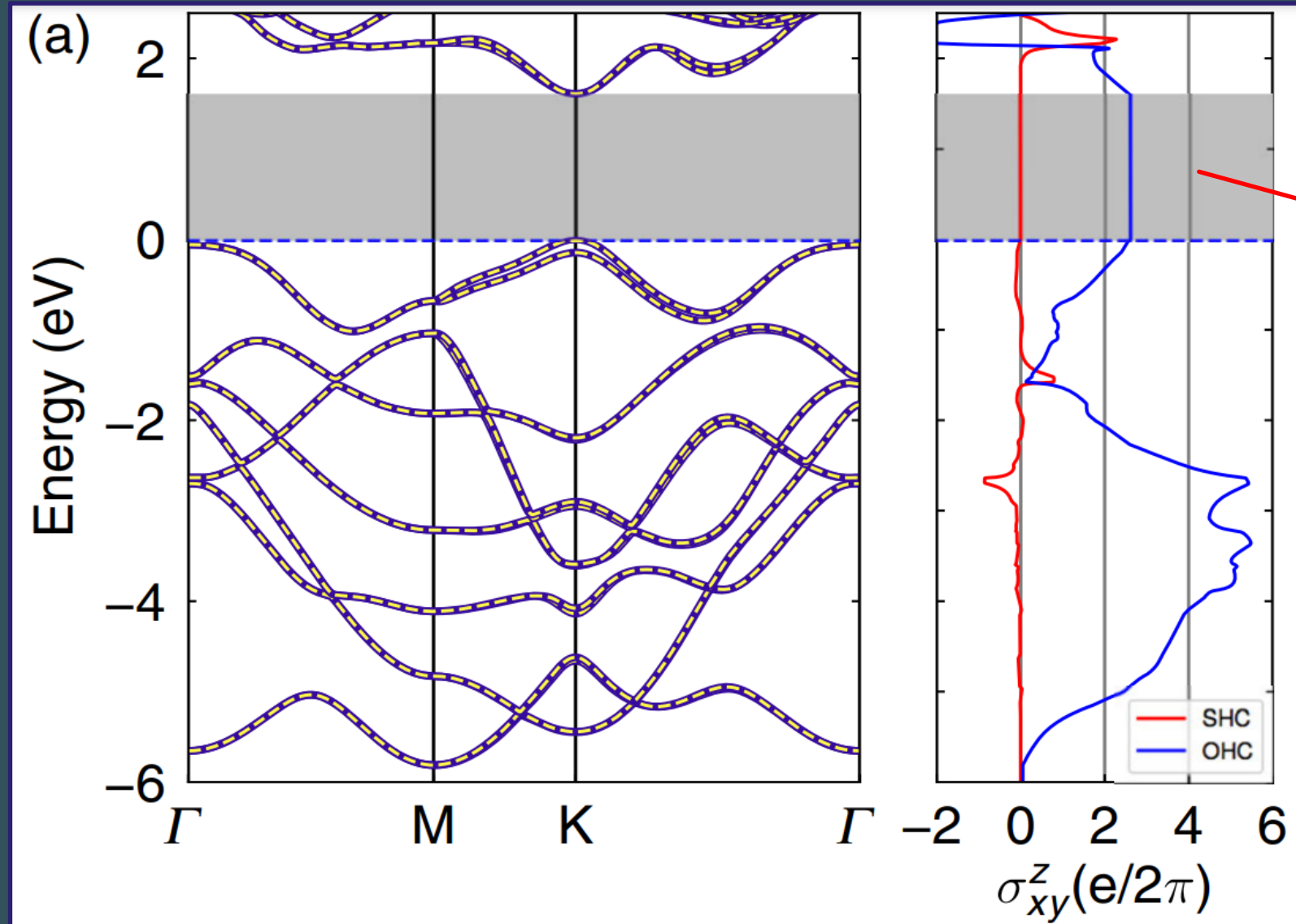
Conduction band: $\{d_{z^2}\}$

Valence band: $\{d_{x^2-y^2} \pm id_{xy}\}$

MX_2 (M=Mo, W... : X=S, Se, Te)



OHE in Two-Dimensional Materials



OH insulator

$\sigma_{OH} \neq 0$
For
 $E_F \in \text{Band-gap}$

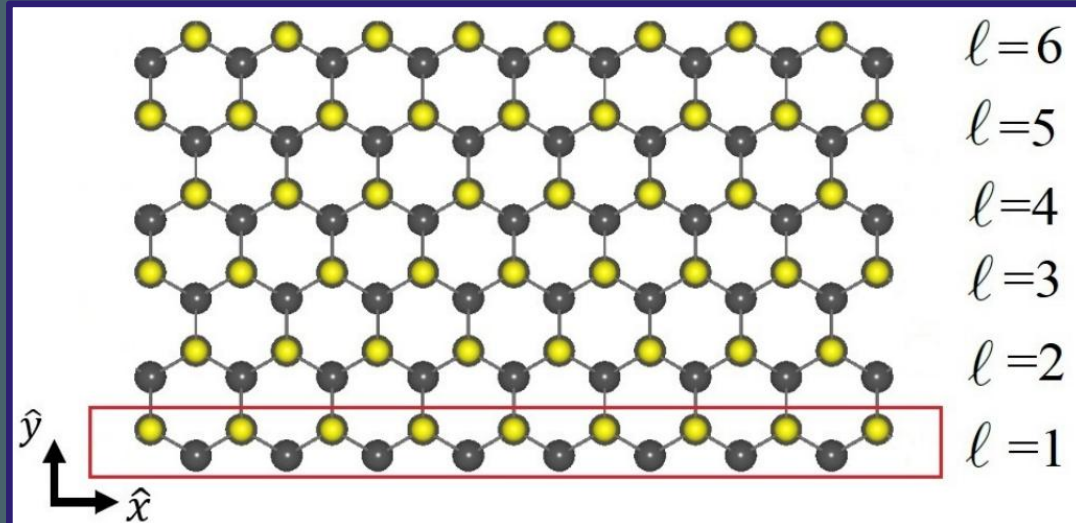
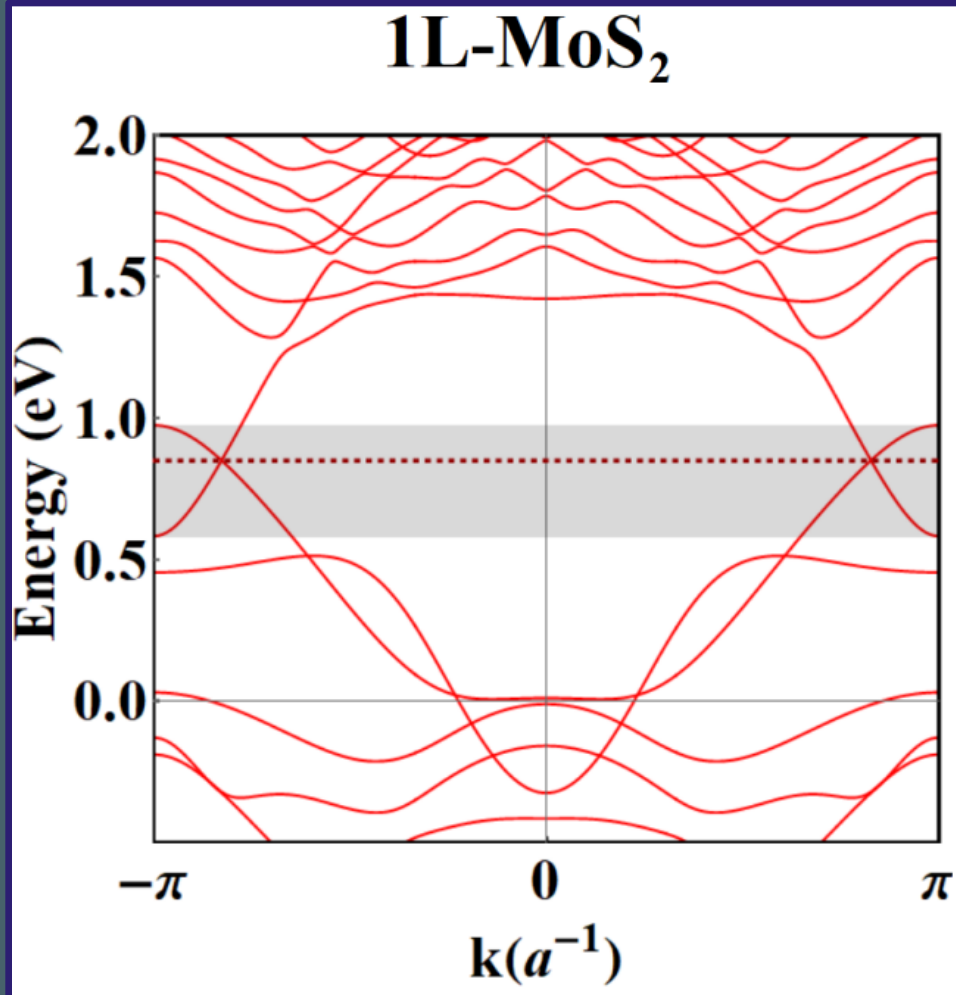
[see. L. M. Canonico et. al., PRB **101**, 075429 (2020) and PRB **101**, 161409(R) (2020)]:

Orbital Chern number

Zigzag Nanoribbons of 2H-TMDs has Lz-polarized edge-states. The **orbital Hall insulating phase** can be indexed by **Orbital Chern Number** [[T. P. Cysne, et. al., PRL 126, 056601 \(2021\)](#) and [PRB 105, 195421 \(2022\)](#)]:

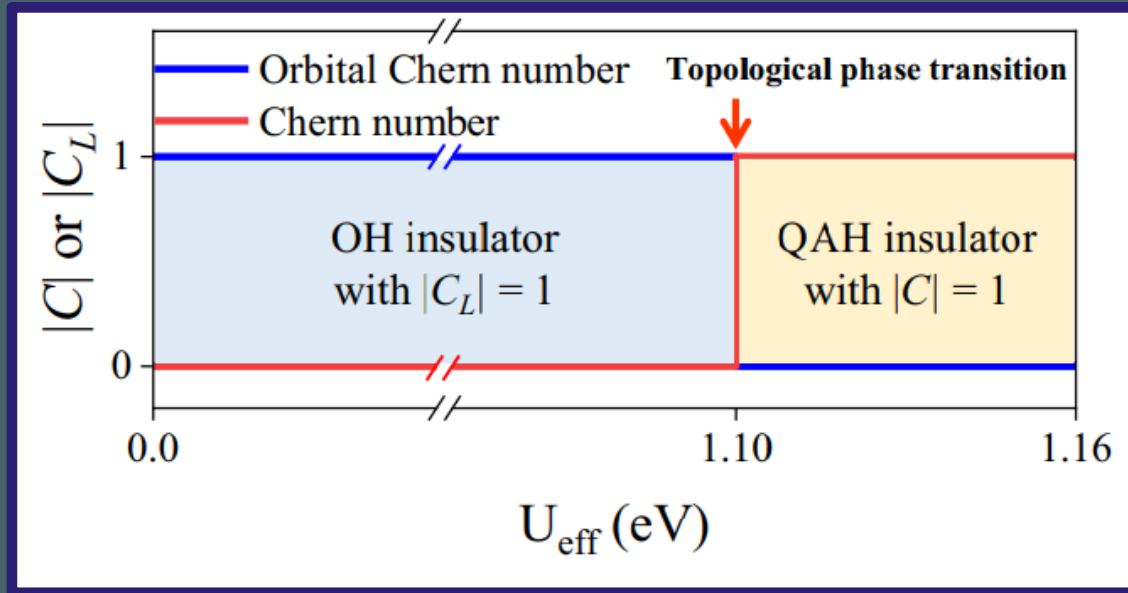
$$C_L = +1$$

Zigzag Nanoribbons:

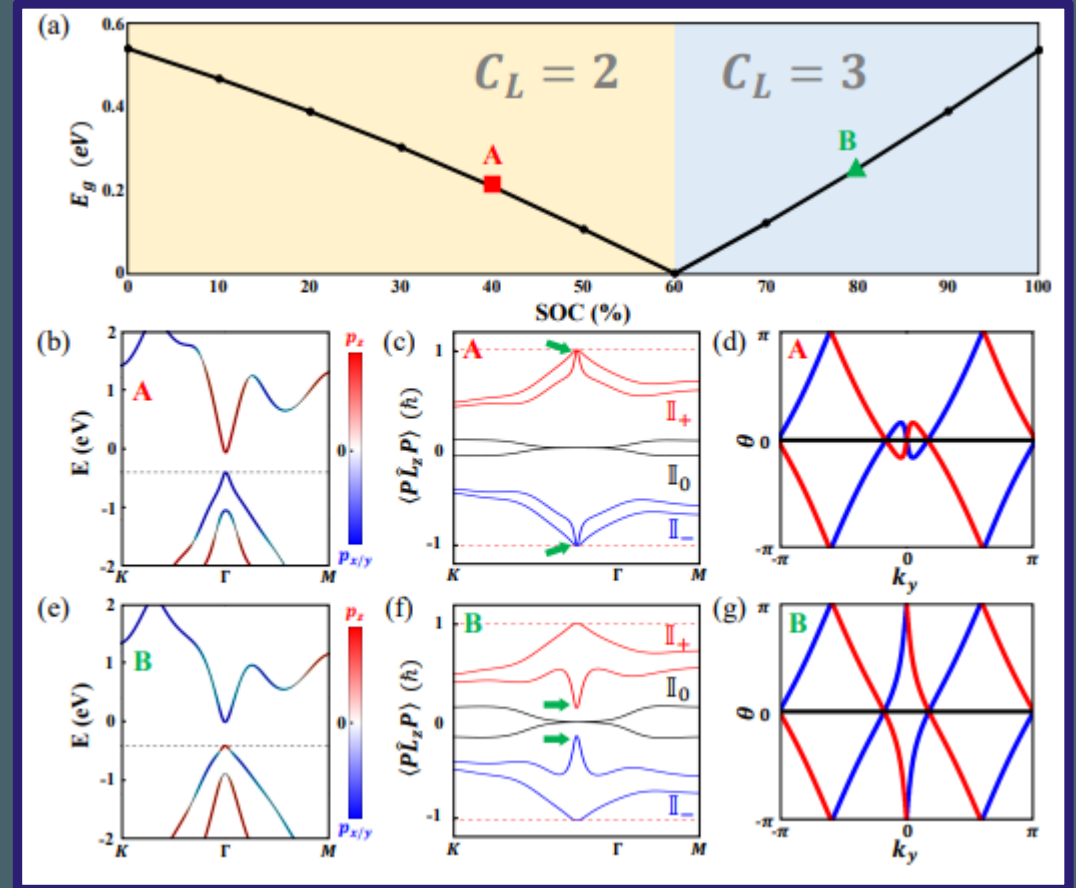


Orbital Chern number

Orbital Chern numbers can undergo topological phase transitions:



[Shilei Ji, et. al. , Phys. Rev. B 108, 224422 (2023)]

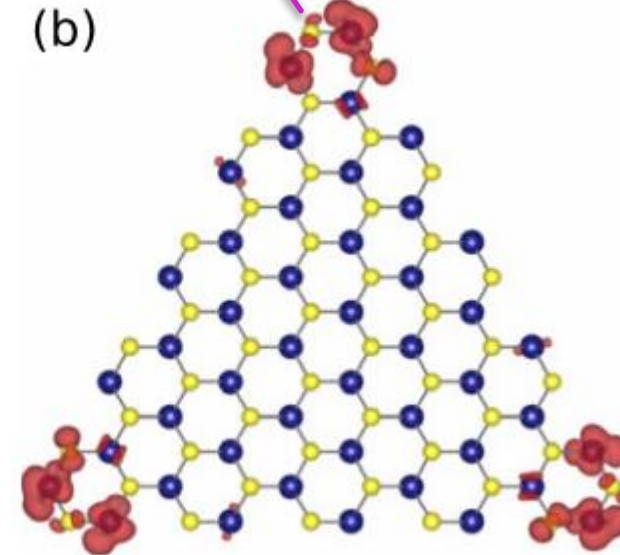
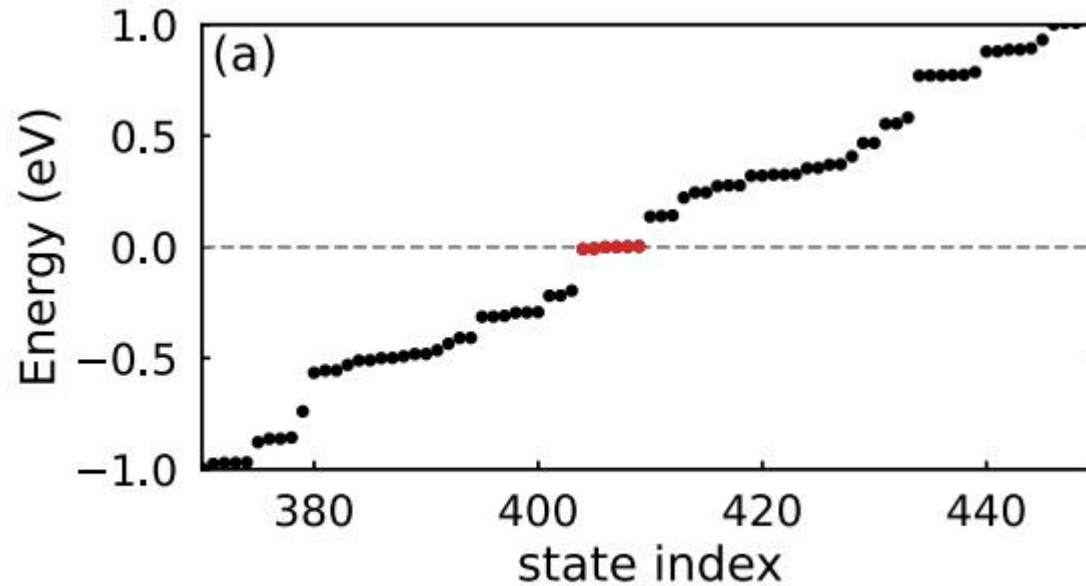


[Y.-T. Yao , et. al. , arXiv:2503.08138 (2025)]

Orbital Hall insulators and high Order topological insulators

[M. Costa, et. al., Phys. Rev. Lett. 130, 116204 \(2023\)](#)

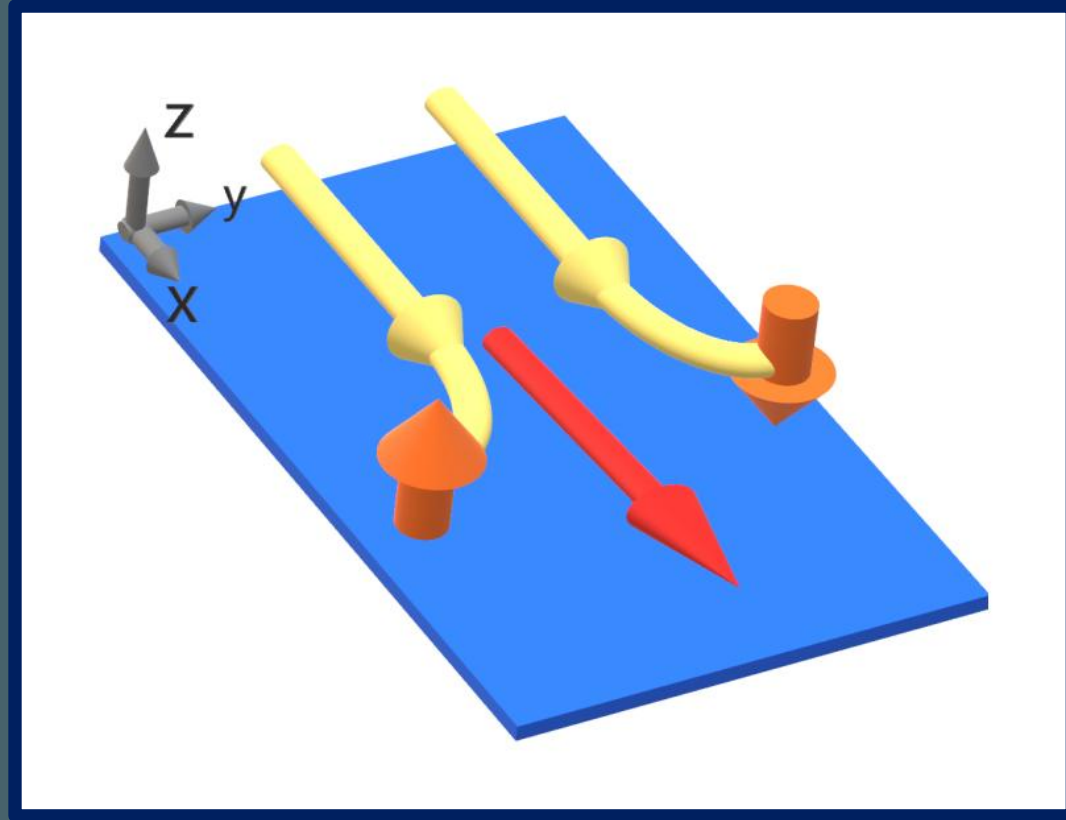
$$Q_c^{(3)} = \frac{e}{3} [K_2^{(3)}] \bmod e$$



- 2H-TMDs are higher-order topological insulators with protected corner states
- This HOTI phase appears to be related to the orbital Hall insulator phase

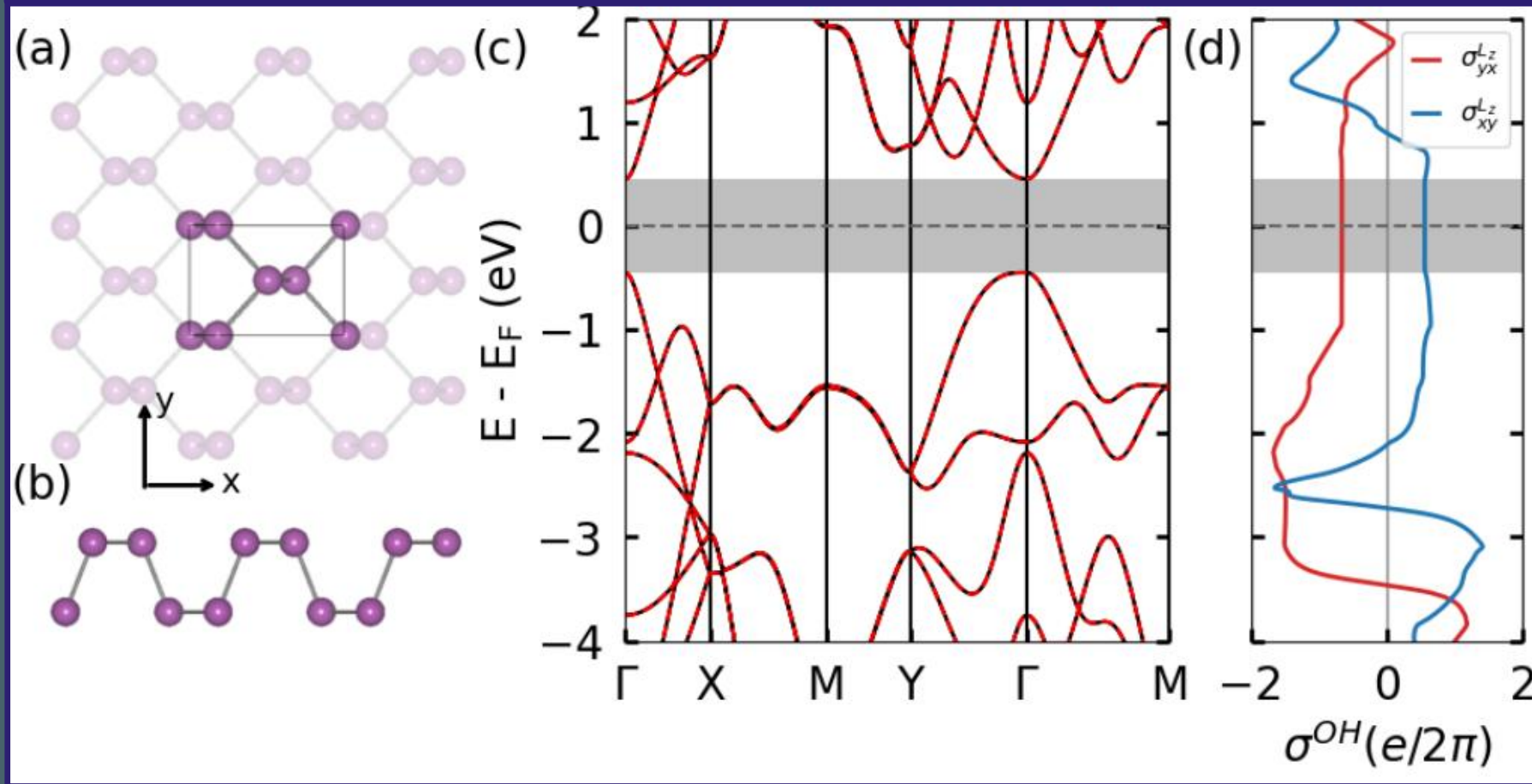
Part III:

OHE in other 2D materials



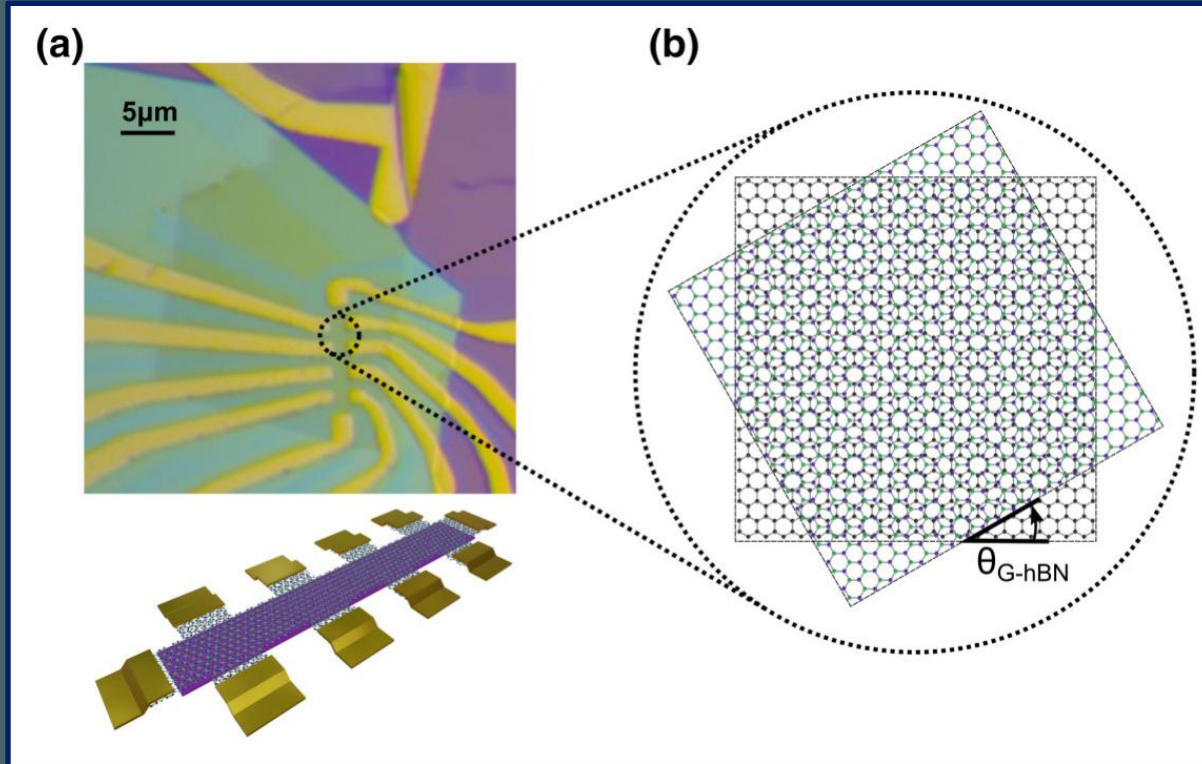
We found other two-dimensional orbital Hall insulators ...

Phosphorene monolayer: anisotropic orbital Hall insulating plateau

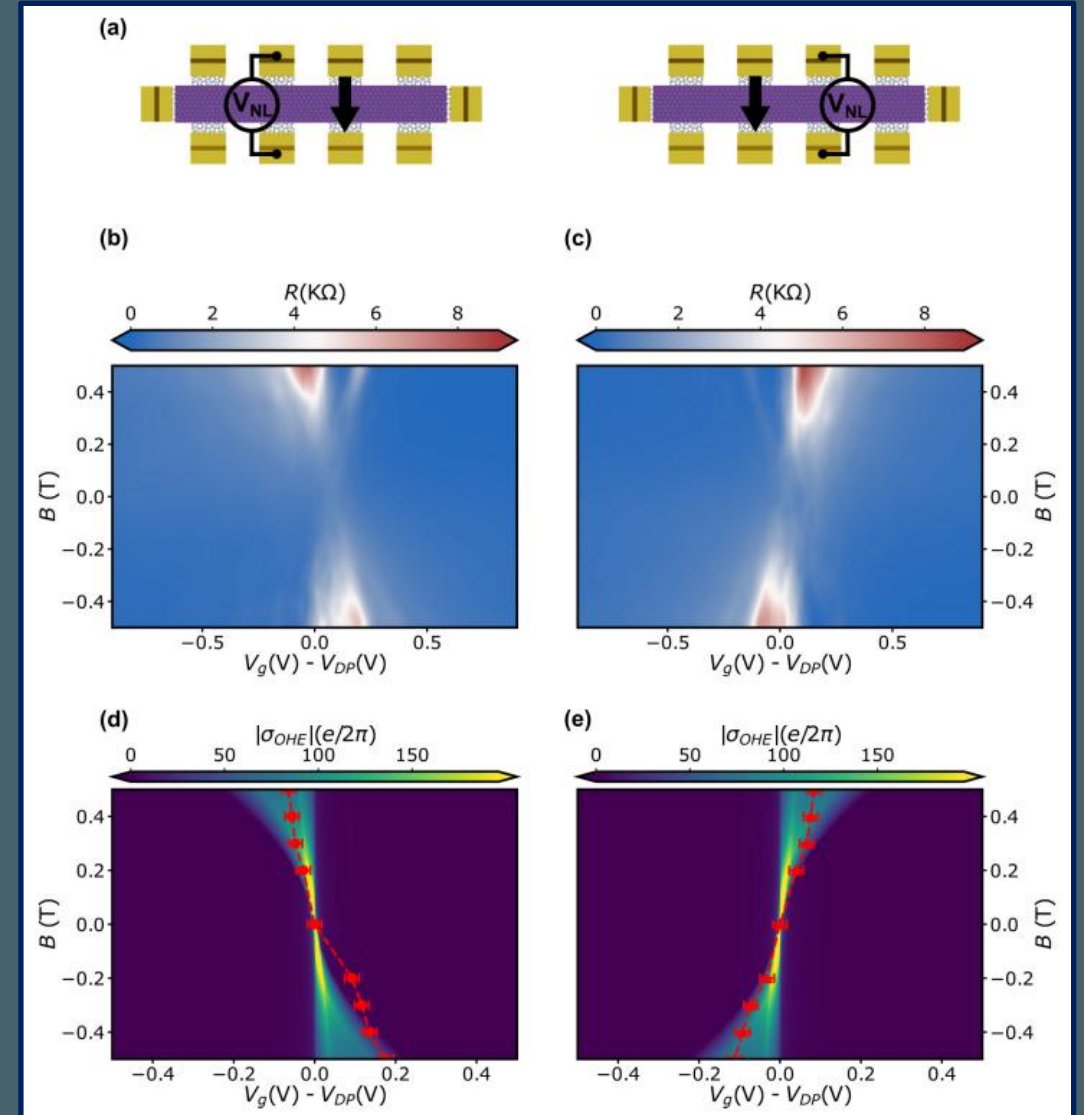


[T. P. Cysne, et. al., PRB **108**, 165415 (2023)]

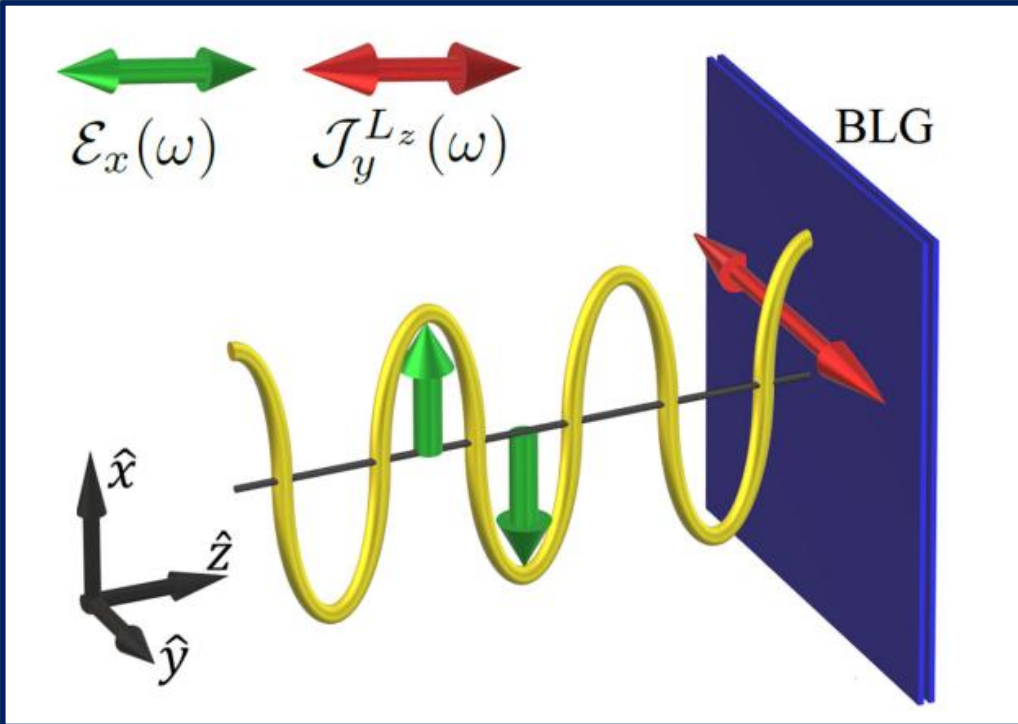
Experimental signature of *OHE*



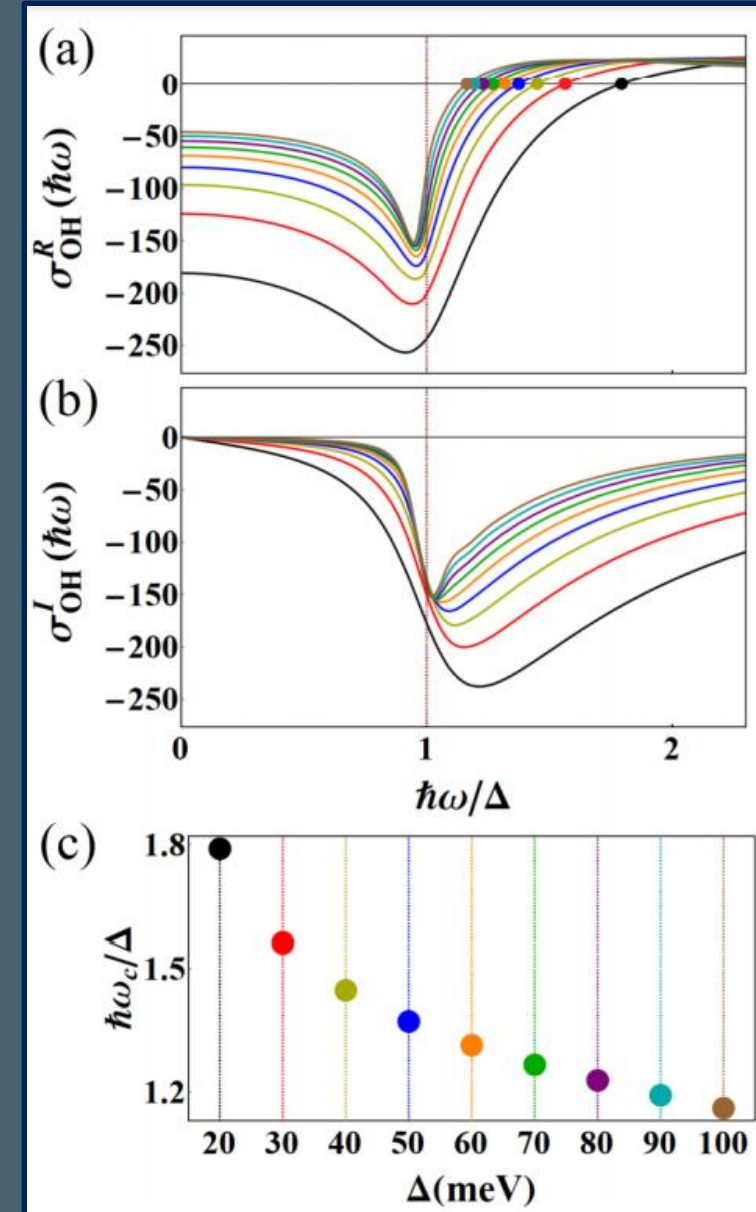
[J. Salvador-Sánchez, et. al., Phys. Rev. Research **6**, 0232 (2024)]



Interaction of materials with light



[T. P. Cysne, W. J. M. Kort-Kamp, and T. G. Rappoport, Phys. Rev. Research **6**, 023271 (2024)]



Final: Perspective for the future

1- Treatment of Disorder: How Disorder can impact the orbital response in materials?

2- Real space calculations: Numerical methods to compute the orbital accumulations in real space.

3- Going beyond intra-atomic approximation: Rigorous treatment of orbital angular momentum operator on the modern theory of orbital magnetization. For what condition intra-atomic approximation is good or bad?

Review on 2D-materials orbitronics

npj | spintronics

Review

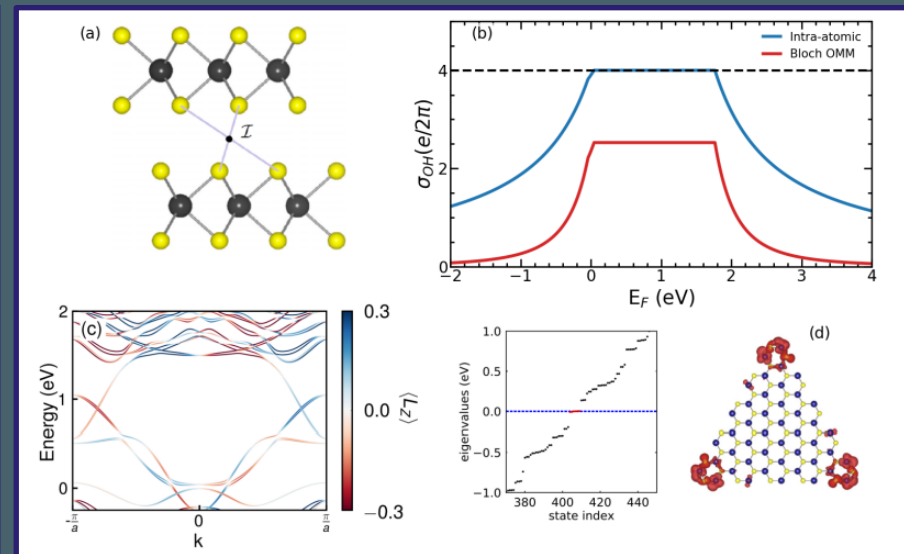
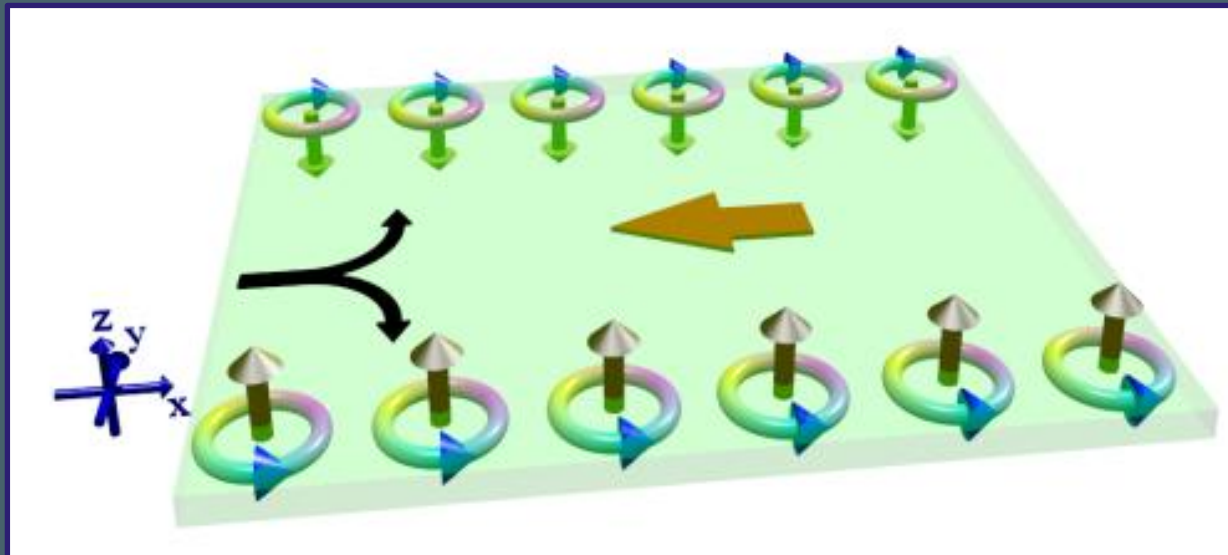


<https://doi.org/10.1038/s44306-025-00103-1>

Orbitronics in two-dimensional materials

Check for updates

Tarik P. Cysne¹✉, Luis M. Canonico², Marcio Costa¹, R. B. Muniz¹ & Tatiana G. Rappoport^{3,4,5}✉



People involved

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Profa. T. G. Rappoport
(UFRJ/BR)



Prof. M. Costa
(UFF/BR)



Dr. L. M. Canonico
(ICN-2/spain)



Dr. T. P. Cysne
(UFF/BR)



Collaborators:

- Filipe Guimarães (Peter Grunberg Institute/Germany)
- M. Buongiorno Nardelli (University of North Texas/USA)





Part IV:

Other research topics

Nanofotônica em materiais 2D

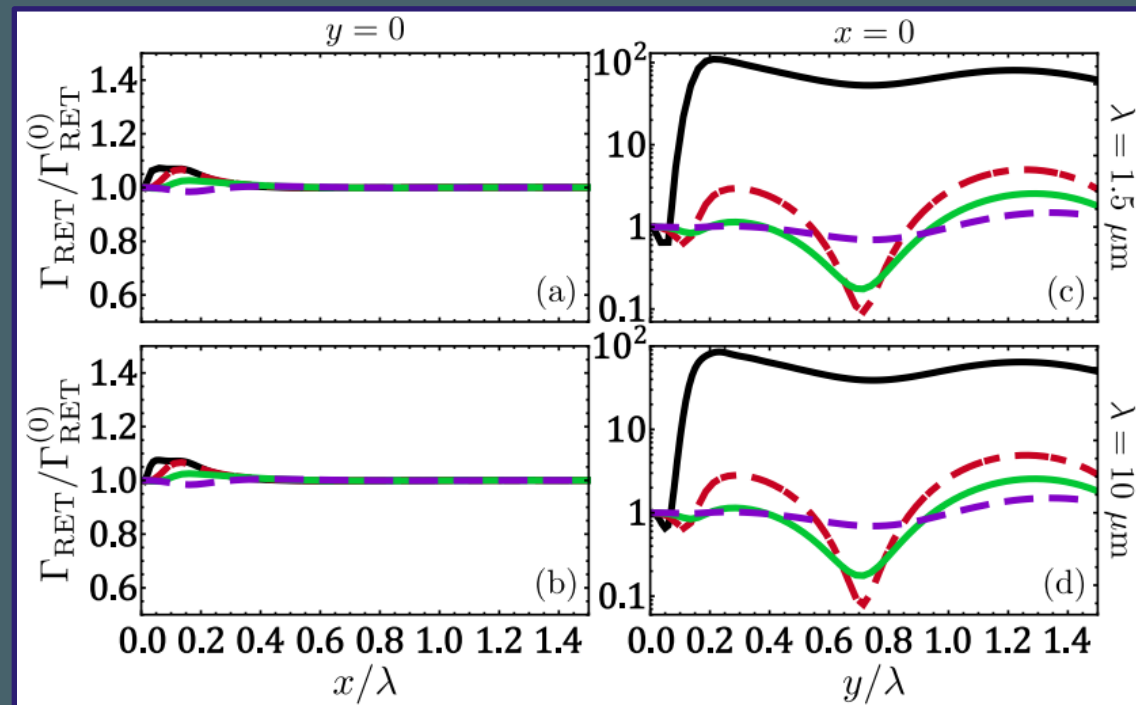
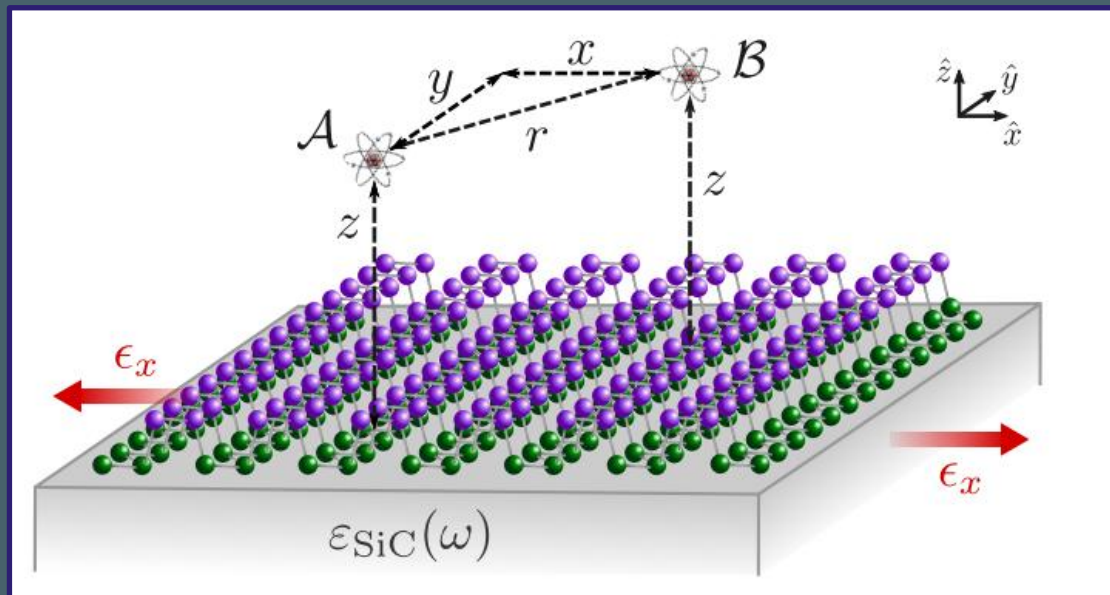
PHYSICAL REVIEW B **111**, 205422 (2025)

Anisotropic resonance energy transfer with strained phosphorene

J. Oliveira-Cony ^{1,*} C. Farina ¹ P. P. Abrantes ^{1,2} and Tarik P. Cysne ^{2,†}

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Local markers for topological phases

PHYSICAL REVIEW B **111**, 035411 (2025)

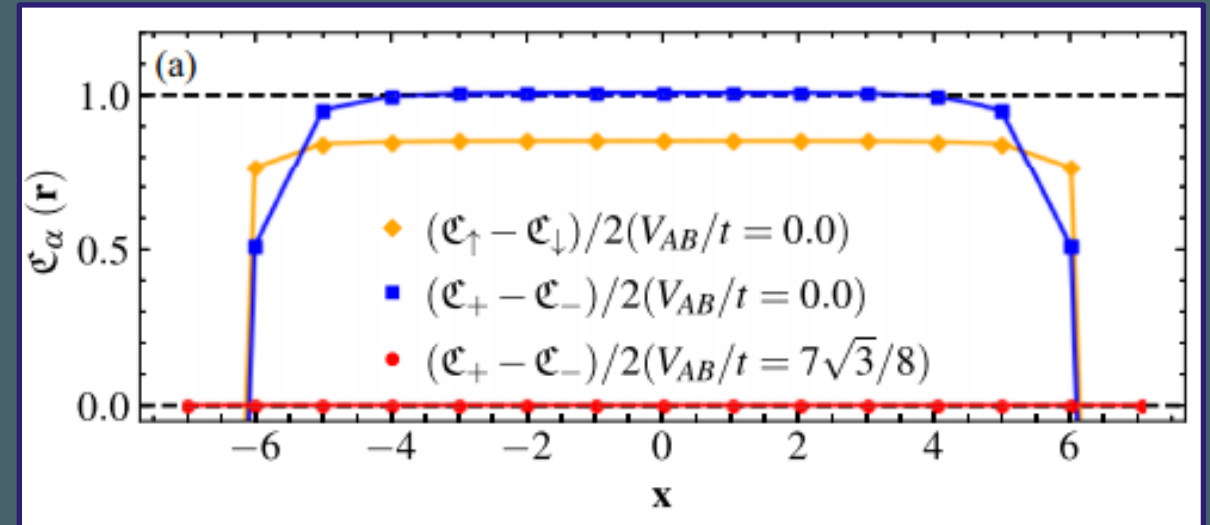
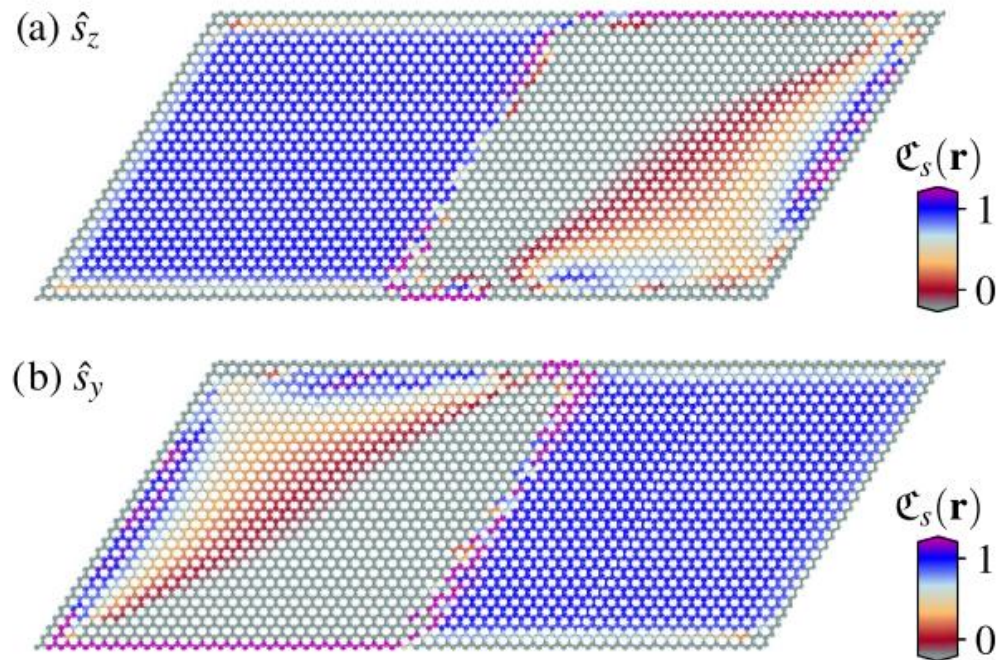
Topological characterization of modified Kane-Mele-Rashba models via local spin Chern marker

Sebastião dos Anjos Sousa-Júnior ^{1,*} Marcus V. de S. Ferraz ² José P. de Lima ² and Tarik P. Cysne ^{3,†}

¹Department of Physics, *University of Houston*, Houston, Texas 77004, USA

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³Instituto de Física, *Universidade Federal Fluminense*, 24210-346 Niterói RJ, Brazil



Local markers for topological phases

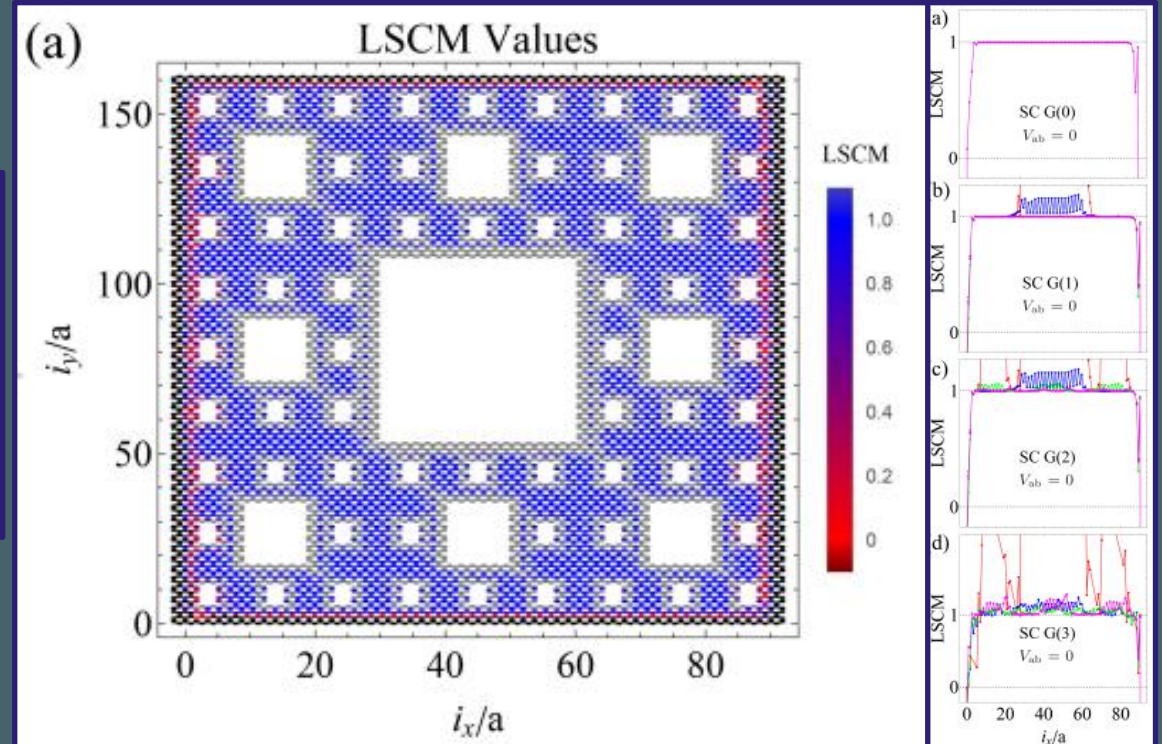
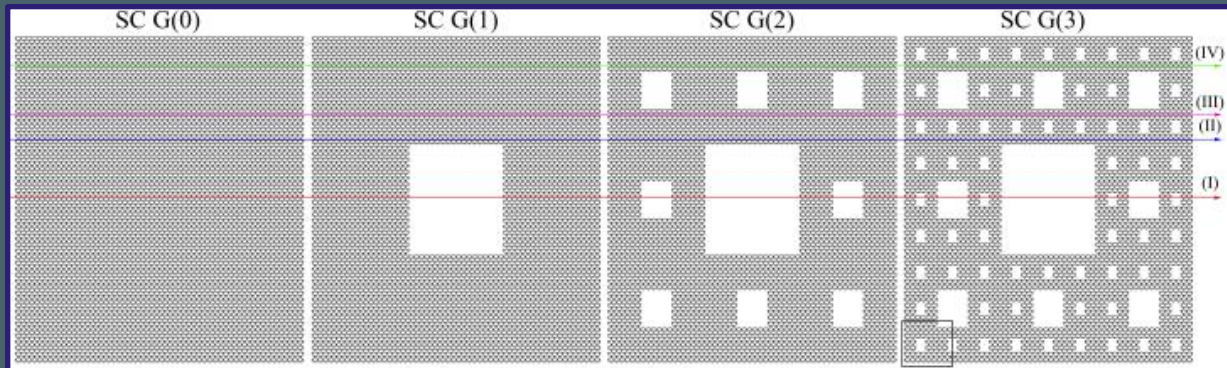
PHYSICAL REVIEW B **111**, 245418 (2025)

Topological phases in fractals: Local spin Chern marker in the Kane-Mele-Rashba model on the Sierpinski carpet

L. L. Lage,^{1,*} A. B. Félix,¹ S. dos A. Sousa-Júnior², A. Latgé¹, and Tarik P. Cysne^{1,†}

¹Instituto de Física, *Universidade Federal Fluminense*, Niterói, Avenida Litorânea sn 24210-340, Rio de Janeiro, Brazil

²Department of Physics, *University of Houston*, Houston, Texas 77204, USA



Instituto de Física da UFF – Niterói/RJ



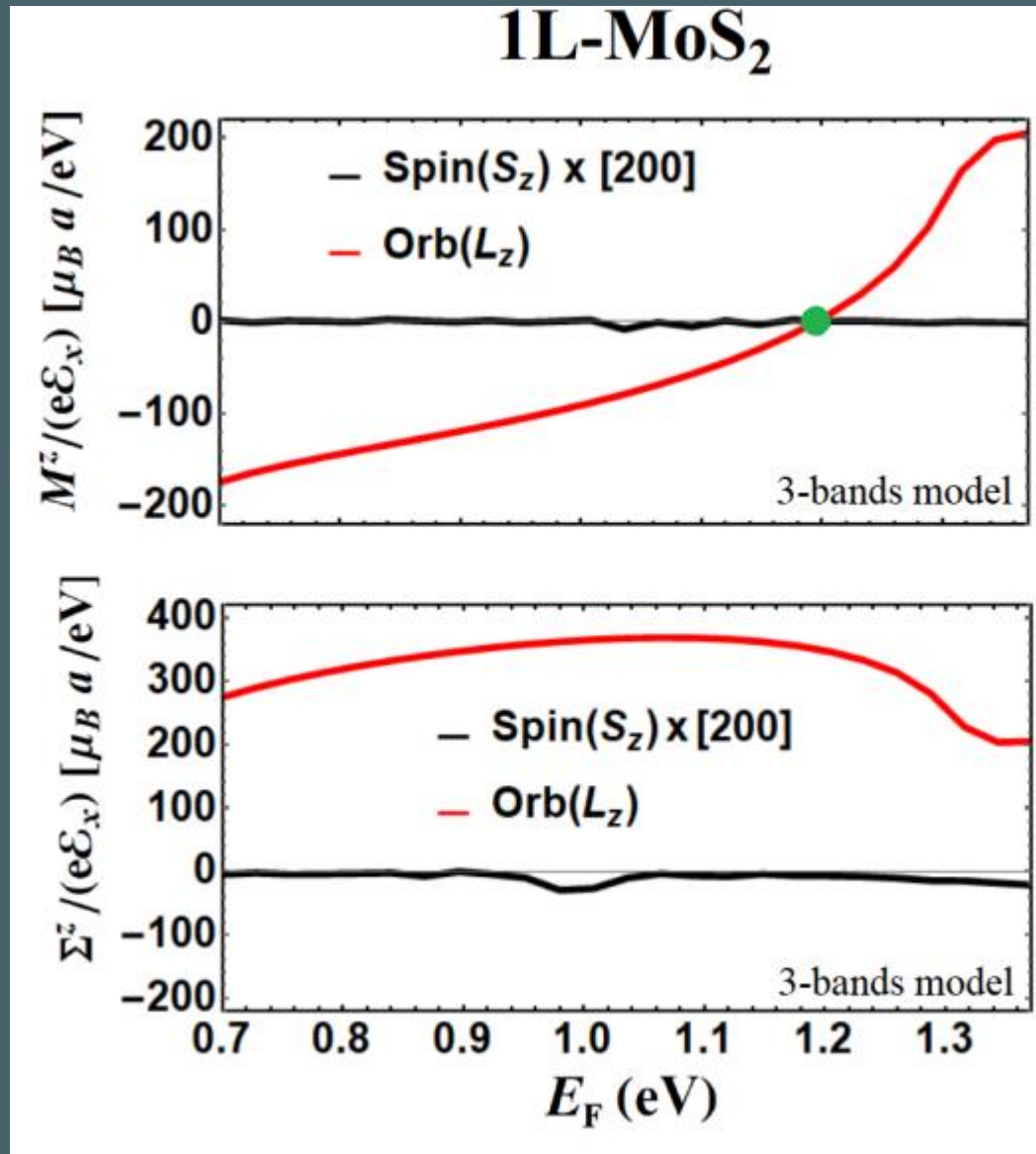
Thanks for your attention!



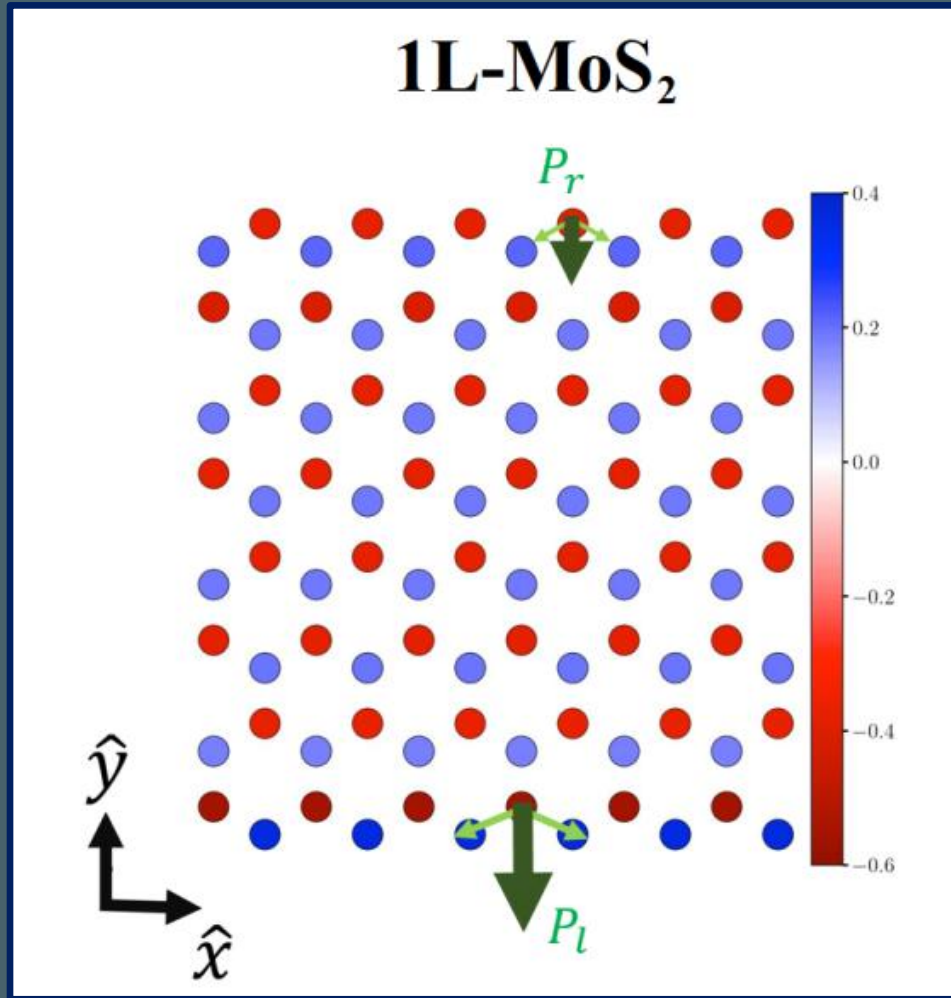
acknowledgements



Contribution from spin sector to magnetoelectric effect in ZZ-NR



Electric polarization x OME in ZZ-NR



Heisenberg's Equation of motion

$$\hat{V}(t) = -e \mathbf{E}(t) \cdot \hat{\mathbf{r}}$$

$$\frac{d\hat{\mathbf{L}}^{\text{ind}}}{dt} = -\frac{i}{\hbar} \left[\hat{\mathbf{L}}^{\text{ind}}, \hat{V}(t) \right] = \hat{\mathbf{r}} \times e \mathbf{E}(t)$$

$$\vec{M}_{orb} = \vec{P}_e \times \vec{E}$$

Topology

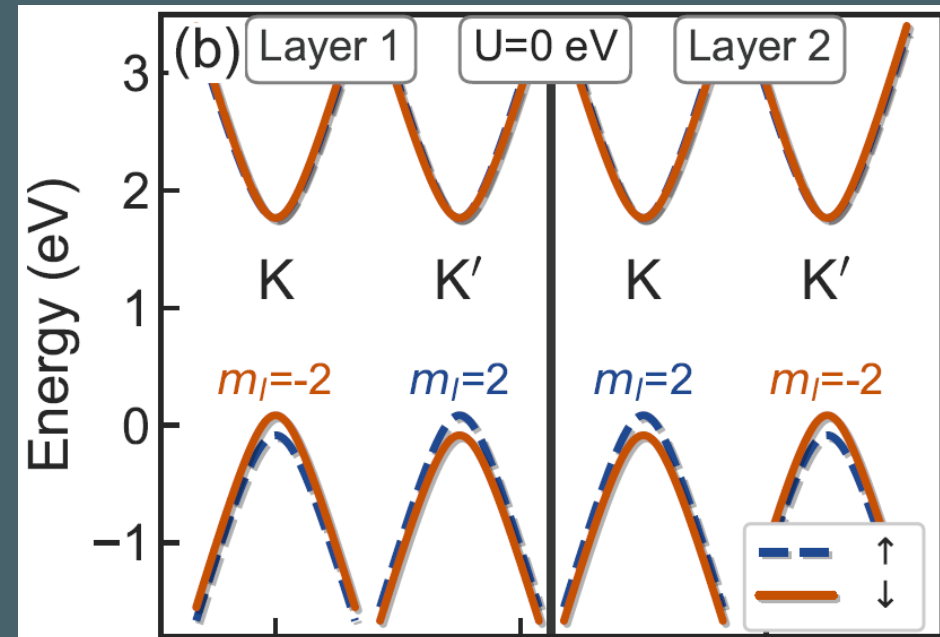
Low energy theory near valleys

$$\tilde{H}(\vec{q}_\tau) = \begin{bmatrix} \Delta & \gamma_+ & 0 & 0 \\ \gamma_- & -\tau s_z \lambda & 0 & t_\perp \\ 0 & 0 & \Delta & \gamma_- \\ 0 & t_\perp & \gamma_+ & \tau s_z \lambda \end{bmatrix} \begin{array}{l} \text{----} |d_{z^2}^1\rangle \\ \text{----} (|d_{x^2-y^2}^1\rangle - i\tau |d_{xy}^1\rangle) / \sqrt{2} \\ \text{----} |d_{z^2}^2\rangle \\ \text{----} (|d_{x^2-y^2}^2\rangle + i\tau |d_{xy}^2\rangle) / \sqrt{2} \end{array}$$

Δ	-----	Energy Gap
λ	-----	SOC (not considered in this talk)
t_\perp	-----	Interlayer hopping
$\gamma_\pm = at(\tau q_x \pm iq_y)$		

Orbital Angular momentum operator:

$$L_z = \text{diag}(0, -2\hbar\tau, 0, 2\hbar\tau)$$



Topology

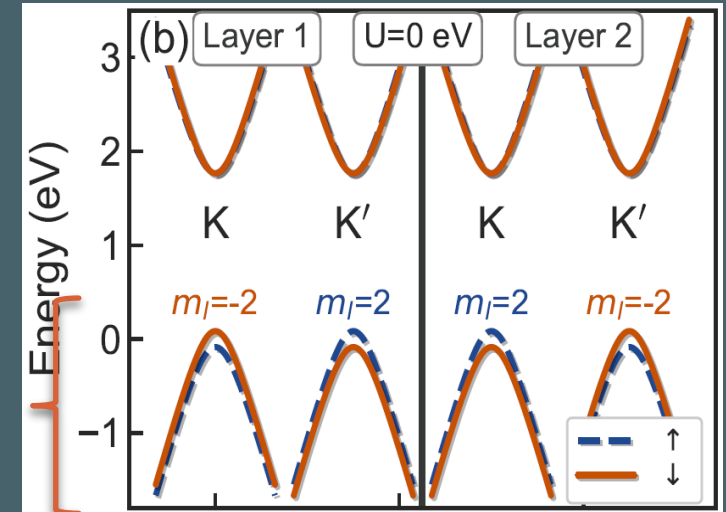
$$\mathbb{L}^v(\vec{k}) = P(\vec{k})L_zP(\vec{k})$$

Eigenstates of
this matrix

$$|\Phi_{n,\tau}^{\pm}(\vec{q})\rangle$$

$$P(\vec{k})$$

Valence Band
Projector



$$\mathcal{C}_L^{\pm} = \frac{1}{2\pi} \int d^2q \sum_{n,\tau} F_{n,\tau}^{\pm}(q)$$

$$F_{n,\tau}^{\pm}(q) = -2\text{Im}[\langle \partial_{q_x} \Phi_{n,\tau}^{\pm}(\vec{q}) | \partial_{q_y} \Phi_{n,\tau}^{\pm}(\vec{q}) \rangle]$$

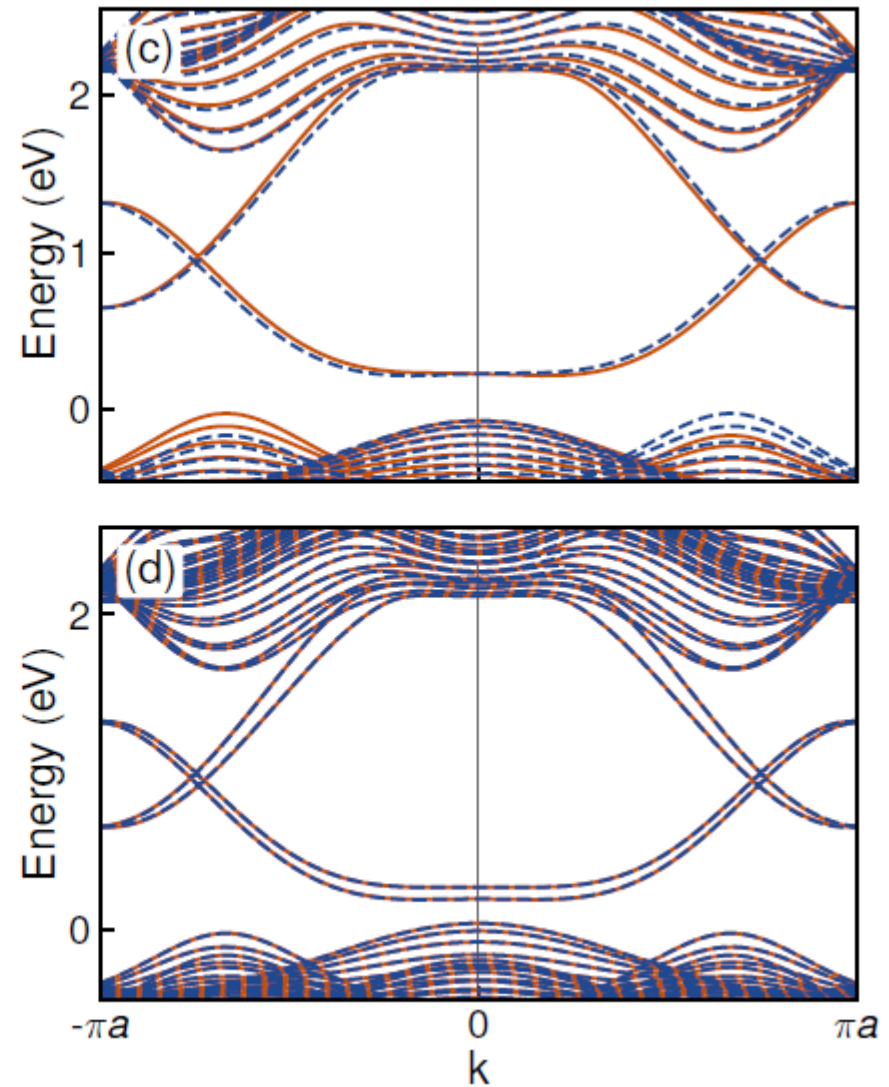
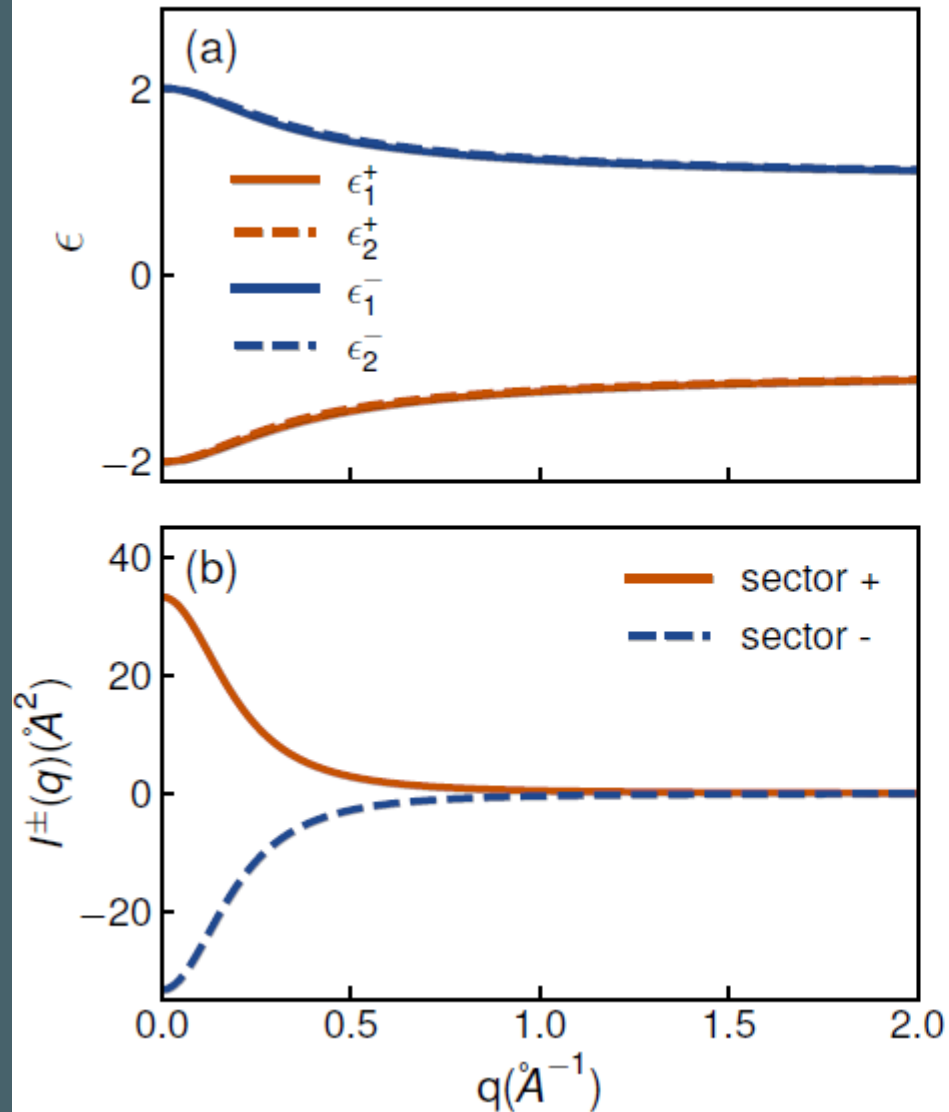
Orbital Chern number!

$$\mathcal{C}_L = (\mathcal{C}_L^{+} - \mathcal{C}_L^{-})/2$$

Topology

$C_L = 2$ for 2L-TMD.

$C_L = 1$ for 1L-TMD.



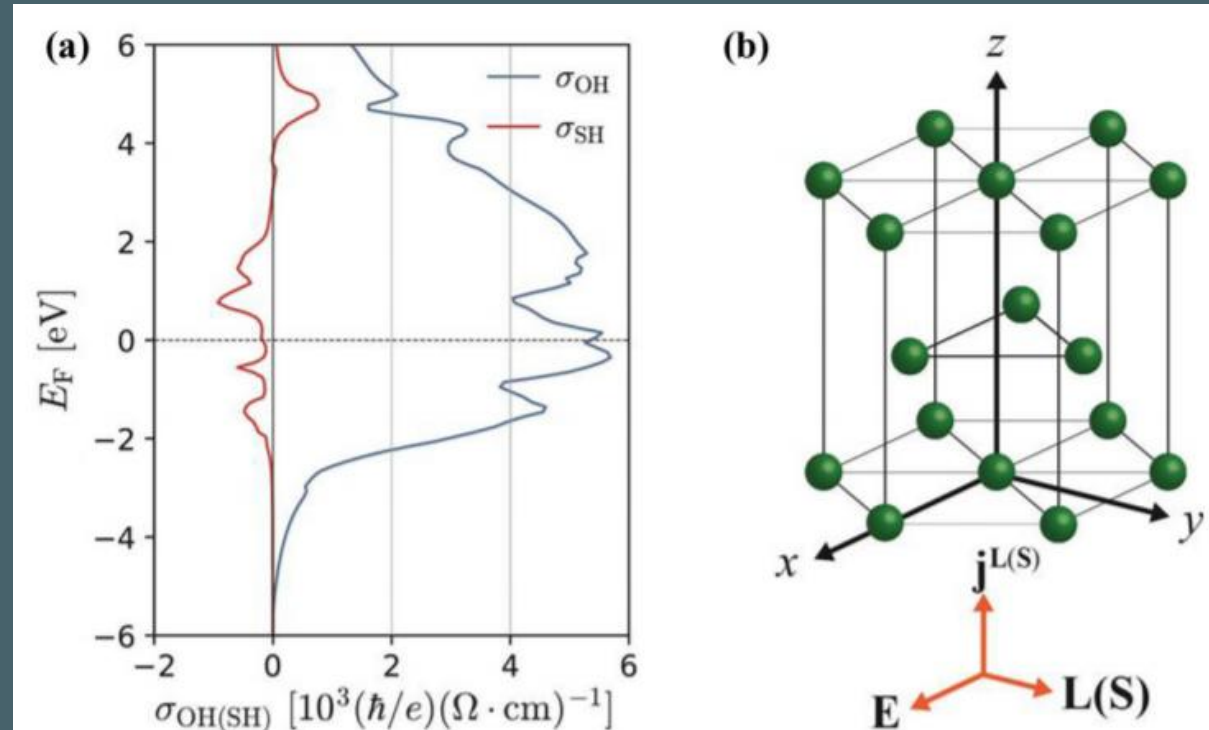
Experiments

PHYSICAL REVIEW RESEARCH **2**, 013127 (2020)

Magnetization switching driven by current-induced torque from weakly spin-orbit coupled Zr

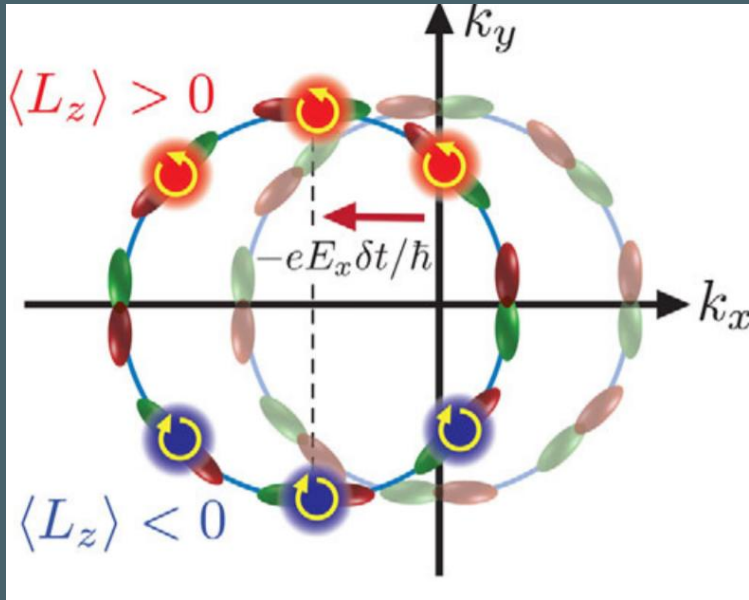
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G. H. Yu,¹ W. He,² H.-W. Lee,³ J. Teng,^{1,‡} and T. Zhu^{2,5,7,§}

Low SOC on Zr. The phenomena should be related to OHE.



Intrinsic mechanism of OHE (3D Metals)

-Intrinsic Mechanism: OHE is a consequence of orbital texture [Figs From “Phys. Rev. Lett. 121, 086602 (2018)”]:



- Even for solids with quenched OAM, the electric field shifts band structure which causes recombination of its orbital texture and produces a transverse flux of OAM.

- Mechanism analogous to spin texture in SHE, but it is robust against dilute disorder (vertex corrections) in centrosymmetric systems.

- OHE precedes the SHE.

- The OHE is converted in SHE by SOC: $\vec{L} \cdot \vec{S}$

- The OHE occurs even in absence of SOC.

